

Freescale Semiconductor Technical Data

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MPC875/MPC870 PowerQUICC[™] Hardware Specifications

This hardware specification contains detailed information on power considerations, DC/AC electrical characteristics, and AC timing specifications for the MPC875/MPC870. The CPU on the MPC875/MPC870 is a 32-bit core built on Power ArchitectureTM technology that incorporates memory management units (MMUs) and instruction and data caches. For functional characteristics of the MPC875/MPC870, refer to the *MPC885 PowerQUICCTM Family Reference Manual*.

To locate published errata or updates for this document, refer to the MPC875/MPC870 product summary page on our website listed on the back cover of this document or, contact your local Freescale sales office.

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1 Overview

The MPC875/MPC870 is a versatile single-chip integrated microprocessor and peripheral combination that can be used in a variety of controller applications and communications and networking systems. The MPC875/MPC870 provides enhanced ATM functionality over that of other ATM-enabled members of the MPC860 family.

Table 1 shows the functionality supported by the MPC875/MPC870.

Part	Cache (Kbytes)		Ethernet		scc	SMC	IIGD	C USB	Security
Tart	I Cache	D Cache	10BaseT	10/100	300	0110	000	Engine	
MPC875	8	8	1	2	1	1	1	Yes	
MPC870	8	8	—	2	_	1	1	No	

Table 1. MPC875/MPC870 Devices

2 Features

The MPC875/MPC870 is comprised of three modules that each use the 32-bit internal bus: a MPC8xx core, a system integration unit (SIU), and a communications processor module (CPM).

The following list summarizes the key MPC875/MPC870 features:

- Embedded MPC8xx core up to 133 MHz
- Maximum frequency operation of the external bus is 80 MHz (in 1:1 mode)
 - The 133-MHz core frequency supports 2:1 mode only
 - The 66-/80-MHz core frequencies support both the 1:1 and 2:1 modes
- Single-issue, 32-bit core (compatible with the Power Architecture definition) with thirty-two 32-bit general-purpose registers (GPRs)
 - The core performs branch prediction with conditional prefetch and without conditional execution
 - 8-Kbyte data cache and 8-Kbyte instruction cache (see Table 1)
 - Instruction cache is two-way, set-associative with 256 sets in 2 blocks
 - Data cache is two-way, set-associative with 256 sets
 - Cache coherency for both instruction and data caches is maintained on 128-bit (4-word) cache blocks
 - Caches are physically addressed, implement a least recently used (LRU) replacement algorithm, and are lockable on a cache block basis
 - MMUs with 32-entry TLB, fully associative instruction and data TLBs
 - MMUs support multiple page sizes of 4, 16, and 512 Kbytes, and 8 Mbytes; 16 virtual address spaces and 16 protection groups
 - Advanced on-chip emulation debug mode
- Up to 32-bit data bus (dynamic bus sizing for 8, 16, and 32 bits)



- Thirty-two address lines
- Memory controller (eight banks)
 - Contains complete dynamic RAM (DRAM) controller
 - Each bank can be a chip select or \overline{RAS} to support a DRAM bank
 - Up to 30 wait states programmable per memory bank
 - Glueless interface to DRAM, SIMMS, SRAM, EPROMs, Flash EPROMs, and other memory devices
 - DRAM controller programmable to support most size and speed memory interfaces
 - Four \overline{CAS} lines, four \overline{WE} lines, and one \overline{OE} line
 - Boot chip-select available at reset (options for 8-, 16-, or 32-bit memory)
 - Variable block sizes (32 Kbytes–256 Mbytes)
 - Selectable write protection
 - On-chip bus arbitration logic
- General-purpose timers
 - Four 16-bit timers or two 32-bit timers
 - Gate mode can enable/disable counting
 - Interrupt can be masked on reference match and event capture
- Two Fast Ethernet controllers (FEC)—Two 10/100 Mbps Ethernet/IEEE Std. 802.3® CDMA/CS that interface through MII and/or RMII interfaces
- System integration unit (SIU)
 - Bus monitor
 - Software watchdog
 - Periodic interrupt timer (PIT)
 - Clock synthesizer
 - Decrementer and time base
 - Reset controller
 - IEEE 1149.1[™] Std. test access port (JTAG)
- Security engine is optimized to handle all the algorithms associated with IPsec, SSL/TLS, SRTP, IEEE 802.11i® standard, and iSCSI processing. Available on the MPC875, the security engine contains a crypto-channel, a controller, and a set of crypto hardware accelerators (CHAs). The CHAs are:
 - Data encryption standard execution unit (DEU)
 - DES, 3DES
 - Two key (K1, K2, K1) or three key (K1, K2, K3)
 - ECB and CBC modes for both DES and 3DES
 - Advanced encryption standard unit (AESU)
 - Implements the Rijndael symmetric key cipher



Features

- ECB, CBC, and counter modes
- 128-, 192-, and 256-bit key lengths
- Message digest execution unit (MDEU)
 - SHA with 160- or 256-bit message digest
 - MD5 with 128-bit message digest
 - HMAC with either algorithm
- Master/slave logic, with DMA
 - 32-bit address/32-bit data
 - Operation at MPC8xx bus frequency
- Crypto-channel supporting multi-command descriptors
 - Integrated controller managing crypto-execution units
 - Buffer size of 256 bytes for each execution unit, with flow control for large data sizes
- Interrupts
 - Six external interrupt request (IRQ) lines
 - Twelve port pins with interrupt capability
 - Twenty-three internal interrupt sources
 - Programmable priority between SCCs
 - Programmable highest priority request
- Communications processor module (CPM)
 - RISC controller
 - Communication-specific commands (for example, GRACEFUL STOP TRANSMIT, ENTER HUNT MODE, and RESTART TRANSMIT)
 - Supports continuous mode transmission and reception on all serial channels
 - 8-Kbytes of dual-port RAM
 - Several serial DMA (SDMA) channels to support the CPM
 - Three parallel I/O registers with open-drain capability
- On-chip 16×16 multiply accumulate controller (MAC)
 - One operation per clock (two-clock latency, one-clock blockage)
 - MAC operates concurrently with other instructions
 - FIR loop—Four clocks per four multiplies
- Four baud-rate generators
 - Independent (can be connected to SCC or SMC)
 - Allows changes during operation
 - Autobaud support option
- SCC (serial communication controller)
 - Ethernet/IEEE 802.3® standard, supporting full 10-Mbps operation
 - HDLC/SDLC



Features

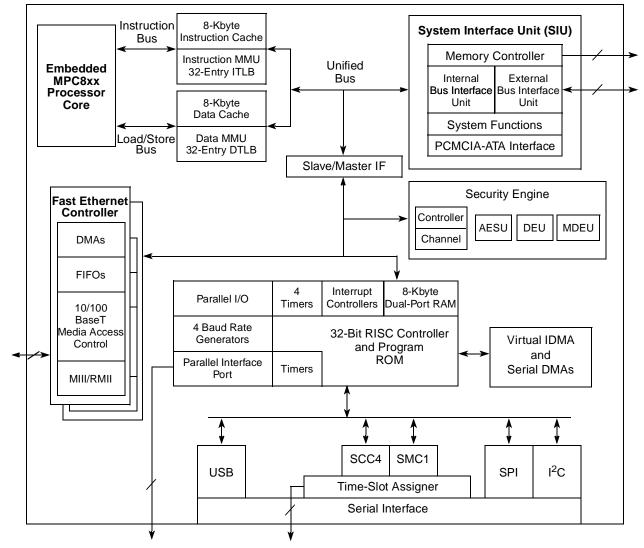
- HDLC bus (implements an HDLC-based local area network (LAN))
- Asynchronous HDLC to support point-to-point protocol (PPP)
- AppleTalk
- Universal asynchronous receiver transmitter (UART)
- Synchronous UART
- Serial infrared (IrDA)
- Binary synchronous communication (BISYNC)
- Totally transparent (bit streams)
- Totally transparent (frame based with optional cyclic redundancy check (CRC))
- SMC (serial management channel)
 - UART (low-speed operation)
 - Transparent
- Universal serial bus (USB)—Supports operation as a USB function endpoint, a USB host controller, or both for testing purposes (loopback diagnostics)
 - USB 2.0 full-/low-speed compatible
 - The USB function mode has the following features:
 - Four independent endpoints support control, bulk, interrupt, and isochronous data transfers
 - CRC16 generation and checking
 - CRC5 checking
 - NRZI encoding/decoding with bit stuffing
 - 12- or 1.5-Mbps data rate
 - Flexible data buffers with multiple buffers per frame
 - Automatic retransmission upon transmit error
 - The USB host controller has the following features:
 - Supports control, bulk, interrupt, and isochronous data transfers
 - CRC16 generation and checking
 - NRZI encoding/decoding with bit stuffing
 - Supports both 12- and 1.5-Mbps data rates (automatic generation of preamble token and data rate configuration). Note that low-speed operation requires an external hub.
 - Flexible data buffers with multiple buffers per frame
 - Supports local loopback mode for diagnostics (12 Mbps only)
- Serial peripheral interface (SPI)
 - Supports master and slave modes
 - Supports multiple-master operation on the same bus
- Inter-integrated circuit (I²C) port
 - Supports master and slave modes
 - Supports a multiple-master environment



Features

- The MPC875 has a time-slot assigner (TSA) that supports one TDM bus (TDMb)
 - Allows SCC and SMC to run in multiplexed and/or non-multiplexed operation
 - Supports T1, CEPT, PCM highway, ISDN basic rate, ISDN primary rate, user-defined
 - 1- or 8-bit resolution
 - Allows independent transmit and receive routing, frame synchronization, and clocking
 - Allows dynamic changes
 - Can be internally connected to two serial channels (one SCC and one SMC)
- PCMCIA interface
 - Master (socket) interface, release 2.1-compliant
 - Supports one independent PCMCIA socket on the MPC875/MPC870
 - Eight memory or I/O windows supported
- Debug interface
 - Eight comparators: four operate on instruction address, two operate on data address, and two
 operate on data
 - Supports conditions: = \neq < >
 - Each watchpoint can generate a break point internally
- Normal high and normal low power modes to conserve power
- 1.8-V core and 3.3-V I/O operation with 5-V TTL compatibility
- The MPC875/MPC870 comes in a 256-pin ball grid array (PBGA) package

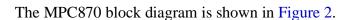




The MPC875 block diagram is shown in Figure 1.

Figure 1. MPC875 Block Diagram





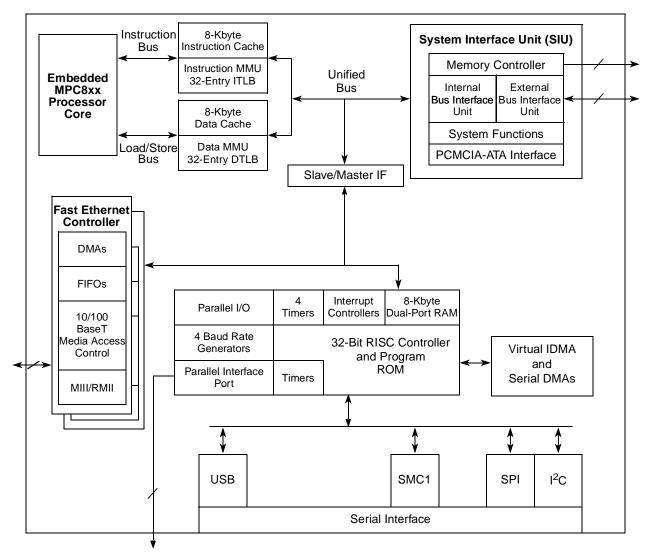


Figure 2. MPC870 Block Diagram





3 Maximum Tolerated Ratings

This section provides the maximum tolerated voltage and temperature ranges for the MPC875/MPC870. Table 2 displays the maximum tolerated ratings and Table 3 displays the operating temperatures.

Rating	Symbol	Value	Unit
Supply voltage ¹	V _{DDL} (core voltage)	-0.3 to 3.4	V
	V _{DDH} (I/O voltage)	-0.3 to 4	V
	V _{DDSYN}	-0.3 to 3.4	V
	Difference between V_{DDL} and V_{DDSYN}	<100	mV
Input voltage ²	V _{in}	$\ensuremath{GND}\xspace - 0.3$ to $\ensuremath{V}\xspace_{\ensuremath{DDH}\xspace}$	V
Storage temperature range	T _{stg}	–55 to +150	°C

Table 2. Maximum Tolerated Ratings

¹ The power supply of the device must start its ramp from 0.0 V.

² Functional operating conditions are provided with the DC electrical specifications in Table 6. Absolute maximum ratings are stress ratings only; functional operation at the maxima is not guaranteed. Stress beyond those listed may affect device reliability or cause permanent damage to the device.

Caution: All inputs that tolerate 5 V cannot be more than 2.5 V greater than V_{DDH}. This restriction applies to power up and normal operation (that is, if the MPC875/MPC870 is unpowered, a voltage greater than 2.5 V must not be applied to its inputs).

Figure 3 shows the undershoot and overshoot voltages at the interfaces of the MPC875/MPC870.

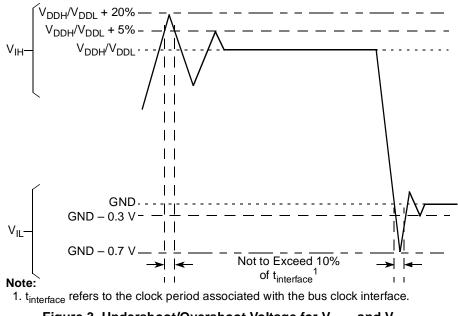


Figure 3. Undershoot/Overshoot Voltage for V_{DDH} and V_{DDL}

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Thermal Characteristics

Rating	Symbol	Value	Unit
Temperature ¹ (standard)	T _{A(min)}	0	°C
	T _{J(max)}	95	°C
Temperature (extended)	T _{A(min)}	-40	°C
	T _{J(max)}	100	°C

Table 3. Operating	Temperatures
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¹ Minimum temperatures are guaranteed as ambient temperature, T_A. Maximum temperatures are guaranteed as junction temperature, T_J.

This device contains circuitry protecting against damage due to high-static voltage or electrical fields; however, it is advised that normal precautions be taken to avoid application of any voltages higher than maximum-rated voltages to this high-impedance circuit. Reliability of operation is enhanced if unused inputs are tied to an appropriate logic voltage level (for example, either GND or V_{DDH}).

4 Thermal Characteristics

Table 4 shows the thermal characteristics for the MPC875/MPC870.

Rating	E	Symbol	Value	Unit	
Junction-to-ambient ¹	Natural convection	Single-layer board (1s)	$R_{\theta JA}^2$	43	°C/W
		Four-layer board (2s2p)	$R_{\theta JMA}{}^3$	29	
	Airflow (200 ft/min)	Single-layer board (1s)	$R_{\theta JMA}{}^3$	36	
		Four-layer board (2s2p)	${\sf R}_{\theta JMA}{}^3$	26	
Junction-to-board ⁴			R _{θJB}	20	
Junction-to-case ⁵			R _{θJC}	10	
Junction-to-package top ⁶	Natural convection		Ψ_{JT}	2	
	Airflow (200 ft/min)		Ψ_{JT}	2	

Table 4. MPC875/MPC870 Thermal Resistance Data

¹ Junction temperature is a function of on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, airflow, power dissipation of other components on the board, and board thermal resistance.

² Per SEMI G38-87 and JEDEC JESD51-2 with the single-layer board horizontal.

³ Per JEDEC JESD51-6 with the board horizontal.

- ⁴ Thermal resistance between the die and the printed-circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.
- ⁵ Indicates the average thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1) with the cold plate temperature used for the case temperature. For exposed pad packages where the pad would be expected to be soldered, junction-to-case thermal resistance is a simulated value from the junction to the exposed pad without contact resistance.

⁶ Thermal characterization parameter indicating the temperature difference between the package top and the junction temperature per JEDEC JESD51-2.





Power Dissipation 5

Table 5 provides information on power dissipation. The modes are 1:1, where CPU and bus speeds are equal, and 2:1, where CPU frequency is twice bus speed.

Die Revision	Bus Mode	Frequency	Typical ¹	Maximum ²	Unit
0	1:1	66 MHz	310	390	mW
		80 MHz	350	430	mW
	2:1	133 MHz	430	495	mW

Table 5. Power Dissipation (P_D)

¹ Typical power dissipation is measured at $V_{DDL} = V_{DDSYN} = 1.8$ V, and V_{DDH} is at 3.3 V. ² Maximum power dissipation at $V_{DDL} = V_{DDSYN} = 1.9$ V, and V_{DDH} is at 3.5 V.

NOTE

The values in Table 5 represent V_{DDL} -based power dissipation and do not include I/O power dissipation over V_{DDH} . I/O power dissipation varies widely by application due to buffer current, depending on external circuitry.

The V_{DDSYN} power dissipation is negligible.

DC Characteristics 6

Table 6 provides the DC electrical characteristics for the MPC875/MPC870.

Table 6. DC Electrical Specifications

Characteristic	Symbol	Min	Мах	Unit
Operating voltage	V _{DDH} (I/O)	3.135	3.465	V
	V _{DDL} (core)	1.7	1.9	V
	V _{DDSYN} 1	1.7	1.9	V
	Difference between V _{DDL} and V _{DDSYN}	_	100	mV
Input high voltage (all inputs except EXTAL and EXTCLK) ²	V _{IH}	2.0	3.465	V
Input low voltage ³	V _{IL}	GND	0.8	V
EXTAL, EXTCLK input high voltage	V _{IHC}	$0.7 \times V_{DDH}$	V _{DDH}	V
Input leakage current, V_{in} = 5.5 V (except TMS, TRST, DSCK, and DSDI pins) for 5-V tolerant pins ¹	l _{in}	—	100	μA
Input leakage current, $V_{in} = V_{DDH}$ (except TMS, TRST, DSCK, and DSDI)	l _{in}	—	10	μA
Input leakage current, $V_{in} = 0 V$ (except TMS, TRST, DSCK, and DSDI pins)	l _{in}	_	10	μA
Input capacitance ⁴	C _{in}	—	20	pF

Characteristic	Symbol	Min	Мах	Unit
Output high voltage, I_{OH} = -2.0 mA, V_{DDH} = 3.0 V (except XTAL and open-drain pins)	V _{OH}	2.4	—	V
$\begin{array}{l} & \text{Output low voltage} \\ \text{I}_{OL} = 2.0 \text{ mA (CLKOUT)} \\ \text{I}_{OL} = 3.2 \text{ mA}^5 \\ \text{I}_{OL} = 5.3 \text{ mA}^6 \\ \text{I}_{OL} = 7.0 \text{ mA (TXD1/PA14, TXD2/PA12)} \\ \text{I}_{OL} = 8.9 \text{ mA (TS, TA, TEA, BI, BB, HRESET, SRESET)} \end{array}$	V _{OL}	_	0.5	V

Table 6. DC Electrical Specifications (continued)

¹ The difference between V_{DDL} and V_{DDSYN} cannot be more than 100 mV.

- ² The signals PA[0:15], PB[14:31], PC[4:15], PD[3:15], PE(14:31), TDI, TDO, TCK, TRST, TMS, MI1_TXEN, and MII_MDIO are 5-V tolerant. The minimum voltage is still 2.0 V.
- 3 V_{IL}(max) for the I²C interface is 0.8 V rather than the 1.5 V as specified in the I²C standard.
- ⁴ Input capacitance is periodically sampled.
- ⁵ A(0:31), TSIZ0/REG, TSIZ1, D(0:31), IRQ(2:4), IRQ6, RD/WR, BURST, IP_B(0:1), PA(0:4), PA(6:7), PA(10:11), PA15, PB19, PB(23:31), PC(6:7), PC(10:13), PC15, PD8, PE(14:31), MII1_CRS, MII_MDIO, MII1_TXEN, and MII1_COL.
- ⁶ BDIP/GPL_B(5), BR, BG, FRZ/IRQ6, CS(0:7), WE(0:3), BS_A(0:3), GPL_A0/GPL_B0, OE/GPL_A1/GPL_B1, GPL_A(2:3)/GPL_B(2:3)/CS(2:3), UPWAITA/GPL_A4, UPWAITB/GPL_B4, GPL_A5, ALE_A, CE1_A, CE2_A, OP(0:3), and BADDR(28:30).

7 Thermal Calculation and Measurement

For the following discussions, $P_D = (V_{DDL} \times I_{DDL}) + P_{I/O}$, where $P_{I/O}$ is the power dissipation of the I/O drivers.

NOTE

The V_{DDSYN} power dissipation is negligible.

7.1 Estimation with Junction-to-Ambient Thermal Resistance

An estimation of the chip junction temperature, T_J, in °C can be obtained from the following equation:

$$T_{J} = T_{A} + (R_{\theta JA} \times P_{D})$$

where:

 T_A = ambient temperature (°C)

 $R_{\theta JA}$ = package junction-to-ambient thermal resistance (°C/W)

 P_D = power dissipation in package

The junction-to-ambient thermal resistance is an industry standard value that provides a quick and easy estimation of thermal performance. However, the answer is only an estimate; test cases have demonstrated that errors of a factor of two (in the quantity $T_I - T_A$) are possible.



Thermal Calculation and Measurement

7.2 Estimation with Junction-to-Case Thermal Resistance

Historically, thermal resistance has frequently been expressed as the sum of a junction-to-case thermal resistance and a case-to-ambient thermal resistance:

$$R_{\theta JA} = R_{\theta JC} + R_{\theta CA}$$

where:

 $R_{\theta JA}$ = junction-to-ambient thermal resistance (°C/W)

 $R_{\theta JC}$ = junction-to-case thermal resistance (°C/W)

 $R_{\theta CA}$ = case-to-ambient thermal resistance (°C/W)

 $R_{\theta JC}$ is device-related and cannot be influenced by the user. The user adjusts the thermal environment to affect the case-to-ambient thermal resistance, $R_{\theta CA}$. For instance, the user can change the airflow around the device, add a heat sink, change the mounting arrangement on the printed-circuit board, or change the thermal dissipation on the printed-circuit board surrounding the device. This thermal model is most useful for ceramic packages with heat sinks where some 90% of the heat flows through the case and the heat sink to the ambient environment. For most packages, a better model is required.

7.3 Estimation with Junction-to-Board Thermal Resistance

A simple package thermal model that has demonstrated reasonable accuracy (about 20%) is a two-resistor model consisting of a junction-to-board and a junction-to-case thermal resistance. The junction-to-case thermal resistance covers the situation where a heat sink is used or where a substantial amount of heat is dissipated from the top of the package. The junction-to-board thermal resistance describes the thermal performance when most of the heat is conducted to the printed-circuit board. It has been observed that the thermal performance of most plastic packages and especially PBGA packages is strongly dependent on the board temperature. If the board temperature is known, an estimate of the junction temperature in the environment can be made using the following equation:

$$T_{\rm J} = T_{\rm B} + (R_{\rm \theta JB} \times P_{\rm D})$$

where:

 $R_{\theta JB}$ = junction-to-board thermal resistance (°C/W)

 $T_B = board temperature (°C)$

 P_D = power dissipation in package

If the board temperature is known and the heat loss from the package case to the air can be ignored, acceptable predictions of junction temperature can be made. For this method to work, the board and board mounting must be similar to the test board used to determine the junction-to-board thermal resistance, namely a 2s2p (board with a power and a ground plane) and vias attaching the thermal balls to the ground plane.

7.4 Estimation Using Simulation

When the board temperature is not known, a thermal simulation of the application is needed. The simple two-resistor model can be used with the thermal simulation of the application [2], or a more accurate and complex model of the package can be used in the thermal simulation.



Power Supply and Power Sequencing

7.5 Experimental Determination

To determine the junction temperature of the device in the application after prototypes are available, the thermal characterization parameter (Ψ_{JT}) can be used to determine the junction temperature with a measurement of the temperature at the top center of the package case using the following equation:

$$\mathbf{T}_{\mathbf{J}} = \mathbf{T}_{\mathbf{T}} + (\boldsymbol{\Psi}_{\mathbf{J}\mathbf{T}} \times \mathbf{P}_{\mathbf{D}})$$

where:

 Ψ_{JT} = thermal characterization parameter

 T_T = thermocouple temperature on top of package

 P_D = power dissipation in package

The thermal characterization parameter is measured per the JESD51-2 specification published by JEDEC using a 40 gauge type T thermocouple epoxied to the top center of the package case. The thermocouple should be positioned so that the thermocouple junction rests on the package. A small amount of epoxy is placed over the thermocouple junction and over about 1 mm of wire extending from the junction. The thermocouple wire is placed flat against the package case to avoid measurement errors caused by the cooling effects of the thermocouple wire.

7.6 References

Semiconductor Equipment and Materials International 805 East Middlefield Rd	(415) 964-5111
Mountain View, CA 94043	
MIL-SPEC and EIA/JESD (JEDEC) specifications	800-854-7179 or
(Available from Global Engineering Documents)	303-397-7956
JEDEC Specifications	http://www.jedec.org

- 1. C.E. Triplett and B. Joiner, "An Experimental Characterization of a 272 PBGA Within an Automotive Engine Controller Module," Proceedings of SemiTherm, San Diego, 1998, pp. 47–54.
- 2. B. Joiner and V. Adams, "Measurement and Simulation of Junction to Board Thermal Resistance and Its Application in Thermal Modeling," Proceedings of SemiTherm, San Diego, 1999, pp. 212–220.

8 Power Supply and Power Sequencing

This section provides design considerations for the MPC875/MPC870 power supply. The MPC875/MPC870 has a core voltage (V_{DDL}) and PLL voltage (V_{DDSYN}), which both operate at a lower voltage than the I/O voltage (V_{DDH}). The I/O section of the MPC875/MPC870 is supplied with 3.3 V across V_{DDH} and V_{SS} (GND).

The signals PA[0:3], PA[8:11], PB15, PB[24:25], PB[28:31], PC[4:7], PC[12:13], PC15, PD[3:15], TDI, TDO, TCK, TRST, TMS, MII_TXEN, and MII_MDIO are 5 V tolerant. No input can be more than 2.5 V greater than V_{DDH}. In addition, 5-V tolerant pins cannot exceed 5.5 V, and remaining input pins cannot exceed 3.465 V. This restriction applies to power up, power down, and normal operation.

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One consequence of multiple power supplies is that when power is initially applied, the voltage rails ramp up at different rates. The rates depend on the nature of the power supply, the type of load on each power supply, and the manner in which different voltages are derived. The following restrictions apply:

- V_{DDL} must not exceed V_{DDH} during power up and power down
- V_{DDL} must not exceed 1.9 V, and V_{DDH} must not exceed 3.465 V

These cautions are necessary for the long-term reliability of the part. If they are violated, the electrostatic discharge (ESD) protection diodes are forward-biased, and excessive current can flow through these diodes. If the system power supply design does not control the voltage sequencing, the circuit shown in Figure 4 can be added to meet these requirements. The MUR420 Schottky diodes control the maximum potential difference between the external bus and core power supplies on power up, and the 1N5820 diodes regulate the maximum potential difference on power down.

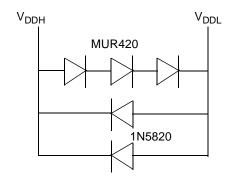


Figure 4. Example Voltage Sequencing Circuit

9 Mandatory Reset Configurations

The MPC875/MPC870 requires a mandatory configuration during reset.

If hardware reset configuration word (HRCW) is enabled, the HRCW[DBGC] value needs to be set to binary X1 in the HRCW and the SIUMCR[DBGC] should be programmed with the same value in the boot code after reset. This can be done by asserting the RSTCONF during HRESET assertion.

If HRCW is disabled, the SIUMCR[DBGC] should be programmed with binary X1 in the boot code after reset by negating the $\overline{\text{RSTCONF}}$ during the $\overline{\text{HRESET}}$ assertion.

The MBMR[GPLB4DIS], PAPAR, PADIR, PBPAR, PBDIR, PCPAR, and PCDIR need to be configured with the mandatory values in Table 7 in the boot code after the reset is negated.

Register/Configuration	Field	Value (Binary)
HRCW (Hardware reset configuration word)	HRCW[DBGC]	X1
SIUMCR (SIU module configuration register)	SIUMCR[DBGC]	X1
MBMR (Machine B mode register)	MBMR[GPLB4DIS}	0
PAPAR (Port A pin assignment register)	PAPAR[5:9] PAPAR[12:13]	0

Table 7. Mandatory Reset Configuration of MPC875/MPC870



Layout Practices

Register/Configuration	Field	Value (Binary)
PADIR (Port A data direction register)	PADIR[5:9] PADIR[12:13]	0
PBPAR (Port B pin assignment register)	PBPAR[14:18] PBPAR[20:22]	0
PBDIR (Port B data direction register)	PBDIR[14:8] PBDIR[20:22]	0
PCPAR (Port C pin assignment register)	PCPAR[4:5] PCPAR[8:9] PCPAR[14]	0
PCDIR (Port C data direction register)	PCDIR[4:5] PCDIR[8:9] PCDIR[14]	0
PDPAR (Port D pin assignment register)	PDPAR[3:7] PDPAR[9:5]	0
PDDIR (Port D data direction register)	PDDIR[3:7] PDDIR[9:15]	0

Table 7. Mandatory Reset Configuration of MPC875/MPC870 (continued)

10 Layout Practices

Each V_{DD} pin on the MPC875/MPC870 should be provided with a low-impedance path to the board's supply. Each GND pin should likewise be provided with a low-impedance path to ground. The power supply pins drive distinct groups of logic on chip. The V_{DD} power supply should be bypassed to ground using at least four 0.1-µF bypass capacitors located as close as possible to the four sides of the package. Each board designed should be characterized and additional appropriate decoupling capacitors should be used if required. The capacitor leads and associated printed-circuit traces connecting to chip V_{DD} and GND should be kept to less than half an inch per capacitor lead. At a minimum, a four-layer board employing two inner layers as V_{DD} and GND planes should be used.

All output pins on the MPC875/MPC870 have fast rise and fall times. Printed circuit (PC) trace interconnection length should be minimized in order to minimize undershoot and reflections caused by these fast output switching times. This recommendation particularly applies to the address and data buses. Maximum PC trace lengths of 6 inches are recommended. Capacitance calculations should consider all device loads as well as parasitic capacitances due to the PC traces. Attention to proper PCB layout and bypassing becomes especially critical in systems with higher capacitive loads because these loads create higher transient currents in the V_{DD} and GND circuits. Pull up all unused inputs or signals that will be inputs during reset. Special care should be taken to minimize the noise levels on the PLL supply pins. For more information, refer to Section 14.4.3, "Clock Synthesizer Power (V_{DDSYN} , V_{SSSYN} , V_{SSSYN1})," in the *MPC885 PowerQUICC*TM *Family Reference Manual*.



The maximum bus speed supported by the MPC875/MPC870 is 80 MHz. Higher-speed parts must be operated in half-speed bus mode (for example, an MPC875/MPC870 used at 133 MHz must be configured for a 66 MHz bus). Table 8 shows the frequency ranges for standard part frequencies in 1:1 bus mode, and Table 9 shows the frequency ranges for standard part frequencies in 2:1 bus mode.

Part Frequency	66 I	MHz	80 MHz		
	Min	Мах	Min	Мах	
Core frequency	40	66.67	40	80	
Bus frequency	40	66.67	40	80	

Table 8. Frequency Ranges for Standard Part Frequencies (1:1 Bus Mode)

Table 9. Frequency Ranges for Standard Part Frequencies (2:1 Bus Mode)

Part Frequency	66 I	MHz	80	MHz	133 MHz		
	Min	Max	Min	Мах	Min	Max	
Core frequency	40	66.67	40	80	40	133	
Bus frequency	20	33.33	20	40	20	66	

Table 10 provides the bus operation timing for the MPC875/MPC870 at 33, 40, 66, and 80 MHz.

The timing for the MPC875/MPC870 bus shown Table 10, assumes a 50-pF load for maximum delays and a 0-pF load for minimum delays. CLKOUT assumes a 100-pF load maximum delay

Table 10. Bus Operation Timings

Num	Characteristic	33	33 MHz		40 MHz		MHz	80 I	WHz	Unit
Num	Characteristic	Min	Мах	Min	Max	Min	Max	Min	Max	Omt
B1	Bus period (CLKOUT), see Table 8	_	—	—	—	_		—	—	ns
B1a	EXTCLK to CLKOUT phase skew—If CLKOUT is an integer multiple of EXTCLK, then the rising edge of EXTCLK is aligned with the rising edge of CLKOUT. For a non-integer multiple of EXTCLK, this synchronization is lost, and the rising edges of EXTCLK and CLKOUT have a continuously varying phase skew.	-2	+2	-2	+2	-2	+2	-2	+2	ns
B1b	CLKOUT frequency jitter peak-to-peak	_	1	_	1		1	_	1	ns
B1c	Frequency jitter on EXTCLK	_	0.50	_	0.50	_	0.50	_	0.50	%
B1d	CLKOUT phase jitter peak-to-peak for OSCLK \ge 15 MHz		4	—	4		4	—	4	ns
	CLKOUT phase jitter peak-to-peak for OSCLK < 15 MHz		5		5		5		5	ns



Num	Characteristic	33	MHz	40 I	MHz	66	MHz	80	Unit	
num	Characteristic	Min	Max	Min	Мах	Min	Мах	Min	Мах	Unit
B2	CLKOUT pulse width low (MIN = $0.4 \times B1$, MAX = $0.6 \times B1$)	12.1	18.2	10.0	15.0	6.1	9.1	5.0	7.5	ns
B3	CLKOUT pulse width high (MIN = $0.4 \times B1$, MAX = $0.6 \times B1$)	12.1	18.2	10.0	15.0	6.1	9.1	5.0	7.5	ns
B4	CLKOUT rise time		4.00	_	4.00	_	4.00	_	4.00	ns
B5	CLKOUT fall time	_	4.00	—	4.00	—	4.00	—	4.00	ns
B7	CLKOUT to A(0:31), BADDR(28:30), RD/ \overline{WR} , BURST, D(0:31) output hold (MIN = 0.25 × B1)	7.60	—	6.30	—	3.80	—	3.13	—	ns
B7a	CLKOUT to TSIZ(0:1), $\overline{\text{REG}}$, $\overline{\text{RSV}}$, $\overline{\text{BDIP}}$, PTR output hold (MIN = 0.25 × B1)	7.60	—	6.30	—	3.80	—	3.13	—	ns
B7b	CLKOUT to \overline{BR} , \overline{BG} , FRZ, VFLS(0:1), VF(0:2) IWP(0:2), LWP(0:1), \overline{STS} output hold (MIN = 0.25 × B1)	7.60	—	6.30	—	3.80	_	3.13	—	ns
B8	CLKOUT to A(0:31), BADDR(28:30), RD/ \overline{WR} , BURST, D(0:31) valid (MAX = 0.25 × B1 + 6.3)	_	13.80	—	12.50	—	10.00	—	9.43	ns
B8a	CLKOUT to TSIZ(0:1), $\overline{\text{REG}}$, $\overline{\text{RSV}}$, $\overline{\text{BDIP}}$, PTR valid (MAX = 0.25 × B1 + 6.3)	_	13.80	—	12.50	—	10.00	—	9.43	ns
B8b	CLKOUT to \overline{BR} , \overline{BG} , VFLS(0:1), VF(0:2), IWP(0:2), FRZ, LWP(0:1), \overline{STS} valid ² (MAX = 0.25 × B1 + 6.3)	_	13.80	—	12.50	—	10.00	—	9.43	ns
B9	CLKOUT to A(0:31), BADDR(28:30), RD/WR, BURST, D(0:31), TSIZ(0:1), REG, RSV, PTR High-Z (MAX = 0.25 × B1 + 6.3)	7.60	13.80	6.30	12.50	3.80	10.00	3.13	9.43	ns
B11	CLKOUT to \overline{TS} , \overline{BB} assertion (MAX = 0.25 × B1 + 6.0)	7.60	13.60	6.30	12.30	3.80	9.80	3.13	9.13	ns
B11a	CLKOUT to \overline{TA} , \overline{BI} assertion (when driven by the memory controller or PCMCIA interface) (MAX = $0.00 \times B1 + 9.30^{1}$)	2.50	9.30	2.50	9.30	2.50	9.80	2.5	9.3	ns
B12	CLKOUT to \overline{TS} , \overline{BB} negation (MAX = 0.25 × B1 + 4.8)	7.60	12.30	6.30	11.00	3.80	8.50	3.13	7.92	ns
B12a	CLKOUT to \overline{TA} , \overline{BI} negation (when driven by the memory controller or PCMCIA interface) (MAX = $0.00 \times B1 + 9.00$)	2.50	9.00	2.50	9.00	2.50	9.00	2.5	9.00	ns
B13	CLKOUT to $\overline{\text{TS}}$, $\overline{\text{BB}}$ High-Z (MIN = 0.25 × B1)	7.60	21.60	6.30	20.30	3.80	14.00	3.13	12.93	ns
B13a	CLKOUT to \overline{TA} , \overline{BI} High-Z (when driven by the memory controller or PCMCIA interface) (MIN = $0.00 \times B1 + 2.5$)	2.50	15.00	2.50	15.00	2.50	15.00	2.5	15.00	ns
B14	CLKOUT to $\overline{\text{TEA}}$ assertion (MAX = $0.00 \times \text{B1} + 9.00$)	2.50	9.00	2.50	9.00	2.50	9.00	2.50	9.00	ns



Nivers	Characteristic	33	MHz	40	MHz	66	MHz	80	MHz	11
Num	Characteristic	Min	Max	Min	Мах	Min	Max	Min	Мах	Unit
B15	CLKOUT to $\overline{\text{TEA}}$ High-Z (MIN = 0.00 × B1 + 2.50)	2.50	15.00	2.50	15.00	2.50	15.00	2.50	15.00	ns
B16	TA, \overline{BI} valid to CLKOUT (setup time) (MIN = 0.00 × B1 + 6.00)	6.00		6.00	—	6.00	—	6	—	ns
B16a	TEA, \overline{KR} , \overline{RETRY} , \overline{CR} valid to CLKOUT (setup time) (MIN = 0.00 × B1 + 4.5)	4.50	—	4.50	—	4.50	—	4.50	—	ns
B16b	\overline{BB} , \overline{BG} , \overline{BR} , valid to CLKOUT (setup time) ² (4MIN = 0.00 × B1 + 0.00)	4.00	—	4.00	—	4.00	—	4.00	—	ns
B17	CLKOUT to \overline{TA} , \overline{TEA} , \overline{BI} , \overline{BB} , \overline{BG} , \overline{BR} valid (hold time) (MIN = 0.00 × B1 + 1.00 ³)	1.00	—	1.00	—	2.00	—	2.00	—	ns
B17a	CLKOUT to $\overline{\text{KR}}$, $\overline{\text{RETRY}}$, $\overline{\text{CR}}$ valid (hold time) (MIN = 0.00 × B1 + 2.00)	2.00	—	2.00	—	2.00	—	2.00	—	ns
B18	D(0:31) valid to CLKOUT rising edge (setup time) ⁴ (MIN = $0.00 \times B1 + 6.00$)	6.00	—	6.00	—	6.00	—	6.00	—	ns
B19	CLKOUT rising edge to D(0:31) valid (hold time) ⁴ (MIN = $0.00 \times B1 + 1.00^5$)	1.00		1.00	—	2.00	_	2.00	—	ns
B20	D(0:31) valid to CLKOUT falling edge (setup time) ⁶ (MIN = $0.00 \times B1 + 4.00$)	4.00	—	4.00	—	4.00	_	4.00	—	ns
B21	CLKOUT falling edge to D(0:31) valid (hold time) ⁶ (MIN = $0.00 \times B1 + 2.00$)	2.00	_	2.00	—	2.00	—	2.00	—	ns
B22	CLKOUT rising edge to \overline{CS} asserted GPCM ACS = 00 (MAX = 0.25 × B1 + 6.3)	7.60	13.80	6.30	12.50	3.80	10.00	3.13	9.43	ns
B22a	CLKOUT falling edge to \overline{CS} asserted GPCM ACS = 10, TRLX = 0 (MAX = 0.00 × B1 + 8.00)	_	8.00	—	8.00		8.00	—	8.00	ns
B22b	CLKOUT falling edge to \overline{CS} asserted GPCM ACS = 11, TRLX = 0, EBDF = 0 (MAX = 0.25 × B1 + 6.3)	7.60	13.80	6.30	12.50	3.80	10.00	3.13	9.43	ns
B22c	CLKOUT falling edge to \overline{CS} asserted GPCM ACS = 11, TRLX = 0, EBDF = 1 (MAX = 0.375 × B1 + 6.6)	10.90	18.00	10.90	16.00	5.20	12.30	4.69	10.93	ns
B23	CLKOUT rising edge to \overline{CS} negated GPCM read access, GPCM write access ACS = 00, TRLX = 0 and CSNT = 0 (MAX = 0.00 × B1 + 8.00)	2.00	8.00	2.00	8.00	2.00	8.00	2.00	8.00	ns
B24	A(0:31) and BADDR(28:30) to \overline{CS} asserted GPCM ACS = 10, TRLX = 0 (MIN = $0.25 \times B1 - 2.00$)	5.60	_	4.30	—	1.80	—	1.13	—	ns
B24a	A(0:31) and BADDR(28:30) to \overline{CS} asserted GPCM ACS = 11, TRLX = 0 (MIN = 0.50 × B1 – 2.00)	13.20		10.50	_	5.60	_	4.25	_	ns



Num	Characteristic	33	MHz	40 1	MHz	66 I	MHz	80	MHz	Unit
NUM	Characteristic	Min	Max	Min	Мах	Min	Max	Min	Мах	Unit
B25	CLKOUT rising edge to \overline{OE} , $\overline{WE}(0:3)/BS_B[0:3]$ asserted (MAX = 0.00 × B1 + 9.00)		9.00		9.00		9.00	—	9.00	ns
B26	CLKOUT rising edge to \overline{OE} negated (MAX = 0.00 × B1 + 9.00)	2.00	9.00	2.00	9.00	2.00	9.00	2.00	9.00	ns
B27	A(0:31) and BADDR(28:30) to \overline{CS} asserted GPCM ACS = 10, TRLX = 1 (MIN = 1.25 × B1 - 2.00)	35.90	_	29.30		16.90	_	13.60		ns
B27a	A(0:31) and BADDR(28:30) to \overline{CS} asserted GPCM ACS = 11, TRLX = 1 (MIN = 1.50 × B1 – 2.00)	43.50	_	35.50		20.70	_	16.75		ns
B28	CLKOUT rising edge to $\overline{WE}(0:3)/BS_B[0:3]$ negated GPCM write access CSNT = 0 (MAX = 0.00 × B1 + 9.00)		9.00		9.00	_	9.00		9.00	ns
B28a	CLKOUT falling edge to $\overline{WE}(0:3)/BS_B[0:3]$ negated GPCM write access TRLX = 0, CSNT = 1, EBDF = 0 (MAX = 0.25 × B1 + 6.80)	7.60	14.30	6.30	13.00	3.80	10.50	3.13	9.93	ns
B28b	CLKOUT falling edge to \overline{CS} negated GPCM write access TRLX = 0, CSNT = 1 ACS = 10 or ACS = 11, EBDF = 0 (MAX = 0.25 × B1 + 6.80)	_	14.30	_	13.00	_	10.50	_	9.93	ns
B28c	CLKOUT falling edge to $\overline{WE}(0:3)/BS_B[0:3]$ negated GPCM write access TRLX = 0, CSNT = 1 write access TRLX = 0, CSNT = 1, EBDF = 1 (MAX = 0.375 × B1 + 6.6)	10.90	18.00	10.90	18.00	5.20	12.30	4.69	11.29	ns
B28d	CLKOUT falling edge to \overline{CS} negated GPCM write access TRLX = 0, CSNT = 1, ACS = 10 or ACS = 11, EBDF = 1 (MAX = 0.375 × B1 + 6.6)	_	18.00	_	18.00	_	12.30	_	11.30	ns
B29	$eq:weighted_$	5.60	_	4.30	—	1.80	_	1.13	_	ns
B29a	$\label{eq:weighted_states} \hline \hline WE(0:3)/BS_B[0:3] \mbox{ negated to } D(0:31) \mbox{ High-Z} \\ GPCM \mbox{ write access, } TRLX = 0, \mbox{ CSNT = 1,} \\ EBDF = 0 \mbox{ (MIN = } 0.50 \times B1 - 2.00) \\ \hline \hline \end{array}$	13.20	—	10.50	—	5.60	—	4.25	_	ns
B29b	\overline{CS} negated to D(0:31) High-Z GPCM write access, ACS = 00, TRLX = 0 and CSNT = 0 (MIN = 0.25 × B1 - 2.00)	5.60		4.30		1.80		1.13		ns
B29c	\overline{CS} negated to D(0:31) High-Z GPCM write access, TRLX = 0, CSNT = 1, ACS = 10 or ACS = 11, EBDF = 0 (MIN = 0.50 × B1 - 2.00)	13.20	_	10.50		5.60	_	4.25	—	ns



		33	MHz	40 M	MHz	66	MHz	80 1	MHz	Unit ns ns ns ns ns ns
Num	Characteristic	Min	Max	Min	Max	Min	Max	Min	Max	Unit
B29d	$\label{eq:weight} \hline \hline WE(0:3)/BS_B[0:3] \mbox{ negated to } D(0:31) \mbox{ High-Z} \\ GPCM \mbox{ write access, } TRLX = 1, \mbox{ CSNT} = 1, \\ EBDF = 0 \mbox{ (MIN} = 1.50 \times B1 - 2.00) \\ \hline \hline \end{tabular}$	43.50		35.50		20.70		16.75		ns
B29e	$\overline{\text{CS}}$ negated to D(0:31) High-Z GPCM write access, TRLX = 1, CSNT = 1, ACS = 10 or ACS = 11, EBDF = 0 (MIN = 1.50 × B1 - 2.00)	43.50	_	35.50		20.70	_	16.75	_	ns
B29f	$\label{eq:weighted_states} \hline \hline WE(0:3/BS_B[0:3]) \ \text{negated to } D(0:31) \ \text{High-Z} \\ \text{GPCM write access, } TRLX = 0, \ \text{CSNT} = 1, \\ \text{EBDF} = 1 \ (\text{MIN} = 0.375 \times \text{B1} - 6.30)^7 \\ \hline \hline \end{array}$	5.00		3.00		0.00		0.00	_	ns
B29g	$\overline{\text{CS}}$ negated to D(0:31) High-Z GPCM write access, TRLX = 0, CSNT = 1 ACS = 10 or ACS = 11, EBDF = 1 (MIN = 0.375 × B1 - 6.30) ⁷	5.00	_	3.00	_	0.00	_	0.00	_	ns
B29h	$\label{eq:weighted} \hline \hline WE(0:3)/BS_B[0:3] \mbox{ negated to } D(0:31) \mbox{ High-Z} \\ GPCM \mbox{ write access, } TRLX = 1, \mbox{ CSNT = 1,} \\ EBDF = 1 \mbox{ (MIN = } 0.375 \times B1 - 3.30) \\ \hline \hline \end{tabular}$	38.40	_	31.10	_	17.50	_	13.85	_	ns
B29i	\overline{CS} negated to D(0:31) (0:3) High-Z GPCM write access, TRLX = 1, CSNT = 1, ACS = 10 or ACS = 11, EBDF = 1 (MIN = 0.375 × B1 - 3.30)	38.40	_	31.10	_	17.50	_	13.85	_	ns
B30	$\overline{\text{CS}}$, $\overline{\text{WE}}(0:3)/\text{BS}_{B}[0:3]$ negated to A(0:31), BADDR(28:30) invalid GPCM write access ⁸ (MIN = 0.25 × B1 - 2.00)	5.60	_	4.30		1.80	_	1.13	_	ns
B30a	$\label{eq:weighted_states} \hline \hline WE(0:3)/BS_B[0:3] \mbox{ negated to } A(0:31), \\ BADDR(28:30) \mbox{ invalid GPCM, write access,} \\ TRLX = 0, \mbox{ CSNT = 1, } \hline CS \mbox{ negated to } A(0:31), \\ \mbox{ invalid GPCM write access } TRLX = 0, \\ CSNT = 1, \mbox{ ACS = 10 or } ACS == 11, \mbox{ EBDF = 0} \\ (MIN = 0.50 \times B1 - 2.00) \\ \hline \hline \hline \hline \end{tabular}$	13.20	_	10.50		5.60	_	4.25	_	ns
B30b	$eq:weighted_$	43.50	_	35.50		20.70	_	16.75	_	ns
B30c	$eq:weighted_$	8.40	_	6.40	_	2.70	_	1.70	_	ns



Num	Characteristic	33	MHz	40	MHz	66	MHz	80	MHz	Unit
Num	Characteristic	Min	Max	Min	Max	Min	Max	Min	Max	Unit
B30d	WE(0:3)/BS_B[0:3] negated to A(0:31), BADDR(28:30) invalid GPCM write access TRLX = 1, CSNT =1, CS negated to A(0:31) invalid GPCM write access TRLX = 1, CSNT = 1, ACS = 10 or 11, EBDF = 1	38.67		31.38		17.83		14.19		ns
B31	CLKOUT falling edge to \overline{CS} valid as requested by control bit CST4 in the corresponding word in the UPM (MAX = $0.00 \times B1 + 6.00$)	1.50	6.00	1.50	6.00	1.50	6.00	1.50	6.00	ns
B31a	CLKOUT falling edge to \overline{CS} valid as requested by control bit CST1 in the corresponding word in the UPM (MAX = $0.25 \times B1 + 6.80$)	7.60	14.30	6.30	13.00	3.80	10.50	3.13	10.00	ns
B31b	CLKOUT rising edge to \overline{CS} valid, as requested by control bit CST2 in the corresponding word in the UPM (MAX = $0.00 \times B1 + 8.00$)	1.50	8.00	1.50	8.00	1.50	8.00	1.50	8.00	ns
B31c	CLKOUT rising edge to \overline{CS} valid, as requested by control bit CST3 in the corresponding word in the UPM (MAX = $0.25 \times B1 + 6.30$)	7.60	13.80	6.30	12.50	3.80	10.00	3.13	9.40	ns
B31d	CLKOUT falling edge to \overline{CS} valid as requested by control bit CST1 in the corresponding word in the UPM EBDF = 1 (MAX = 0.375 × B1 + 6.6)	13.30	18.00	11.30	16.00	7.60	12.30	4.69	11.30	ns
B32	CLKOUT falling edge to $\overline{\text{BS}}$ valid as requested by control bit BST4 in the corresponding word in the UPM (MAX = 0.00 × B1 + 6.00)	1.50	6.00	1.50	6.00	1.50	6.00	1.50	6.00	ns
B32a	CLKOUT falling edge to \overline{BS} valid as requested by control bit BST1 in the corresponding word in the UPM, EBDF = 0 (MAX = 0.25 × B1 + 6.80)	7.60	14.30	6.30	13.00	3.80	10.50	3.13	10.00	ns
B32b	CLKOUT rising edge to $\overline{\text{BS}}$ valid, as requested by control bit BST2 in the corresponding word in the UPM (MAX = $0.00 \times \text{B1} + 8.00$)	1.50	8.00	1.50	8.00	1.50	8.00	1.50	8.00	ns
B32c	CLKOUT rising edge to $\overline{\text{BS}}$ valid, as requested by control bit BST3 in the corresponding word in the UPM (MAX = $0.25 \times \text{B1} + 6.80$)	7.60	14.30	6.30	13.00	3.80	10.50	3.13	10.00	ns
B32d	CLKOUT falling edge to \overline{BS} valid as requested by control bit BST1 in the corresponding word in the UPM, EBDF = 1 (MAX = 0.375 × B1 + 6.60)	13.30	18.00	11.30	16.00	7.60	12.30	4.49	11.30	ns
B33	CLKOUT falling edge to $\overline{\text{GPL}}$ valid as requested by control bit GxT4 in the corresponding word in the UPM (MAX = 0.00 × B1 + 6.00)	1.50	6.00	1.50	6.00	1.50	6.00	1.50	6.00	ns



NI		33	MHz	40 I	MHz	66 I	MHz	80	MHz	11
Num	Characteristic	Min	Max	Min	Max	Min	Max	Min	Max	Unit
B33a	CLKOUT rising edge to $\overline{\text{GPL}}$ valid as requested by control bit GxT3 in the corresponding word in the UPM (MAX = $0.25 \times B1 + 6.80$)	7.60	14.30	6.30	13.00	3.80	10.50	3.13	10.00	ns
B34	A(0:31), BADDR(28:30), and D(0:31) to \overline{CS} valid, as requested by control bit CST4 in the corresponding word in the UPM (MIN = $0.25 \times B1 - 2.00$)	5.60	_	4.30	_	1.80	_	1.13	_	ns
B34a	A(0:31), BADDR(28:30), and D(0:31) to \overline{CS} valid, as requested by control bit CST1 in the corresponding word in the UPM (MIN = 0.50 × B1 – 2.00)	13.20	_	10.50	_	5.60	_	4.25	_	ns
B34b	A(0:31), BADDR(28:30), and D(0:31) to \overline{CS} valid, as requested by CST2 in the corresponding word in UPM (MIN = 0.75 × B1 – 2.00)	20.70	_	16.70	_	9.40	_	6.80	_	ns
B35	A(0:31), BADDR(28:30) to \overline{CS} valid as requested by control bit BST4 in the corresponding word in the UPM (MIN = $0.25 \times B1 - 2.00$)	5.60	_	4.30	_	1.80	_	1.13	_	ns
B35a	A(0:31), BADDR(28:30), and D(0:31) to $\overline{\text{BS}}$ valid as requested by BST1 in the corresponding word in the UPM (MIN = 0.50 × B1 - 2.00)	13.20	_	10.50	_	5.60	_	4.25	_	ns
B35b	A(0:31), BADDR(28:30), and D(0:31) to $\overline{\text{BS}}$ valid as requested by control bit BST2 in the corresponding word in the UPM (MIN = 0.75 × B1 - 2.00)	20.70	_	16.70	_	9.40	_	7.40	_	ns
B36	A(0:31), BADDR(28:30), and D(0:31) to $\overline{\text{GPL}}$ valid as requested by control bit GxT4 in the corresponding word in the UPM (MIN = $0.25 \times \text{B1} - 2.00$)	5.60	_	4.30	_	1.80	_	1.13	_	ns
B37	UPWAIT valid to CLKOUT falling edge ⁹ (MIN = $0.00 \times B1 + 6.00$)	6.00	—	6.00	—	6.00	—	6.00	—	ns
B38	CLKOUT falling edge to UPWAIT valid ⁹ (MIN = $0.00 \times B1 + 1.00$)	1.00	—	1.00	—	1.00	—	1.00	—	ns
B39	$\overline{\text{AS}}$ valid to CLKOUT rising edge ¹⁰ (MIN = 0.00 × B1 + 7.00)	7.00		7.00		7.00	_	7.00		ns
B40	A(0:31), TSIZ(0:1), RD/WR, BURST valid to CLKOUT rising edge (MIN = 0.00 × B1 + 7.00)	7.00	—	7.00	—	7.00	-	7.00	—	ns
B41	$\overline{\text{TS}}$ valid to CLKOUT rising edge (setup time) (MIN = 0.00 × B1 + 7.00)	7.00	—	7.00	_	7.00	—	7.00		ns

Table 10. Bus Operation Timings (continued)



Table 10. Bus	Operation	Timings	(continued)
---------------	-----------	---------	-------------

Num	Characteristic	33	MHz	40 M	MHz	66 I	MHz	80 N	MHz	Unit
Num	Unaracteristic	Min	Max	Min	Max	Min	Max	Min	Max	onit
B42	CLKOUT rising edge to \overline{TS} valid (hold time) (MIN = 0.00 × B1 + 2.00)	2.00	—	2.00	_	2.00	_	2.00	_	ns
B43	AS negation to memory controller signals negation (MAX = TBD)	—	TBD	_	TBD	_	TBD	_	TBD	ns

¹ For part speeds above 50 MHz, use 9.80 ns for B11a.

² The timing required for BR input is relevant when the MPC875/MPC870 is selected to work with the internal bus arbiter. The timing for BG input is relevant when the MPC875/MPC870 is selected to work with the external bus arbiter.

³ For part speeds above 50 MHz, use 2 ns for B17.

⁴ The D(0:31) input timings B18 and B19 refer to the rising edge of the CLKOUT in which the TA input signal is asserted.

⁵ For part speeds above 50 MHz, use 2 ns for B19.

⁶ The D(0:31) input timings B20 and B21 refer to the falling edge of the CLKOUT. This timing is valid only for read accesses controlled by chip-selects under control of the user-programmable machine (UPM) in the memory controller, for data beats where DLT3 = 1 in the RAM words. (This is only the case where data is latched on the falling edge of CLKOUT.)

⁷ This formula applies to bus operation up to 50 MHz.

⁸ The timing B30 refers to \overline{CS} when ACS = 00 and to $\overline{WE}(0:3)$ when CSNT = 0.

⁹ The signal UPWAIT is considered asynchronous to the CLKOUT and synchronized internally. The timings specified in B37 and B38 are specified to enable the freeze of the UPM output signals as described in Figure 20.

¹⁰ The AS signal is considered asynchronous to the CLKOUT. The timing B39 is specified in order to allow the behavior specified in Figure 23.



Figure 5 provides the control timing diagram.

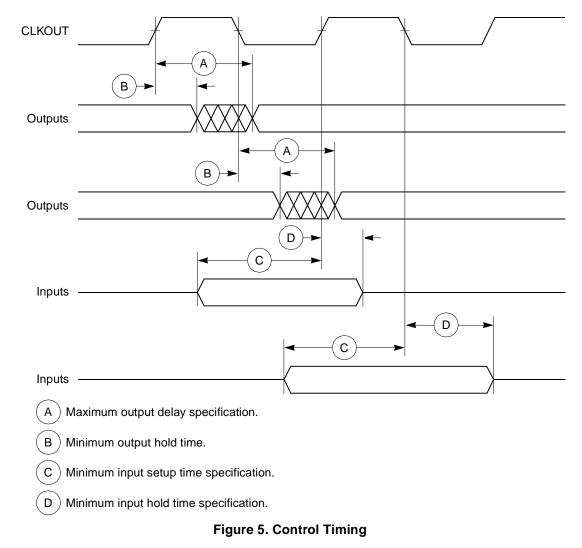


Figure 6 provides the timing for the external clock.

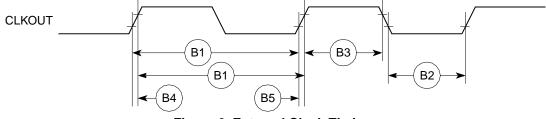


Figure 6. External Clock Timing



Figure 7 provides the timing for the synchronous output signals.

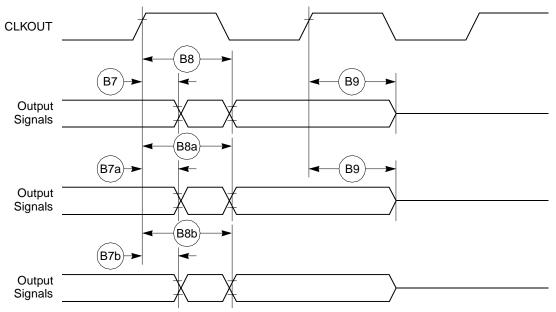


Figure 7. Synchronous Output Signals Timing

Figure 8 provides the timing for the synchronous active pull-up and open-drain output signals.

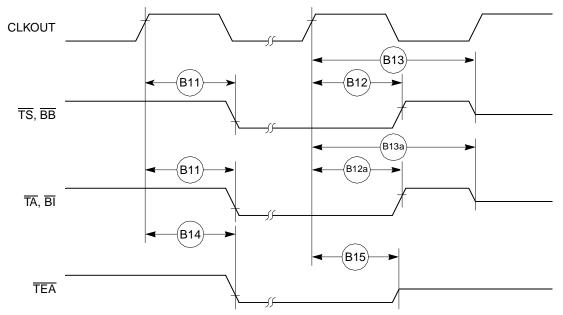


Figure 8. Synchronous Active Pull-Up Resistor and Open-Drain Outputs Signals Timing



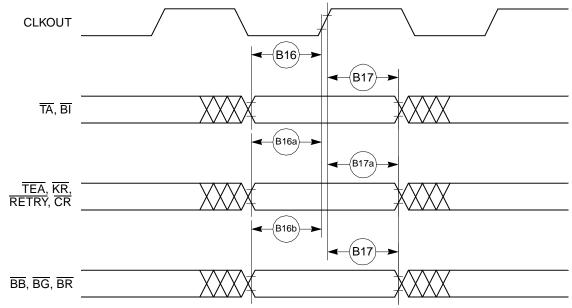


Figure 9 provides the timing for the synchronous input signals.



Figure 10 provides normal case timing for input data. It also applies to normal read accesses under the control of the user-programmable machine (UPM) in the memory controller.

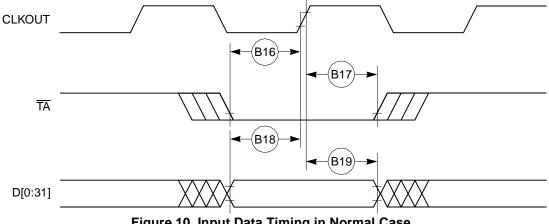


Figure 10. Input Data Timing in Normal Case



Figure 11 provides the timing for the input data controlled by the UPM for data beats where DLT3 = 1 in the UPM RAM words. (This is only the case where data is latched on the falling edge of CLKOUT.)

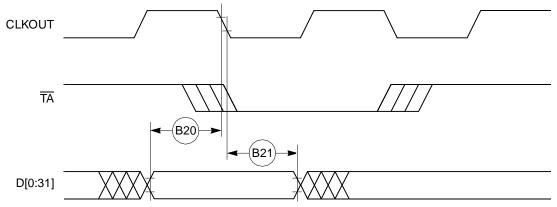


Figure 11. Input Data Timing when Controlled by UPM in the Memory Controller and DLT3 = 1

Figure 12 through Figure 15 provide the timing for the external bus read controlled by various GPCM factors.

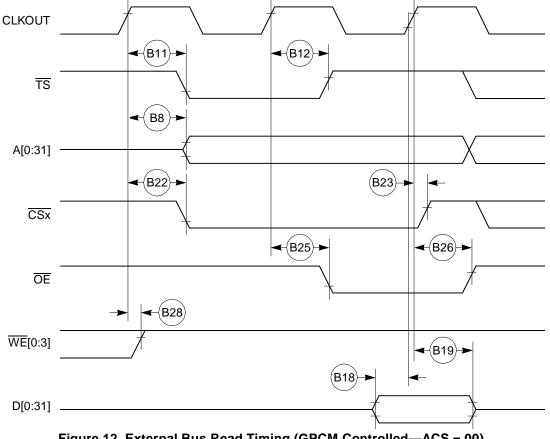
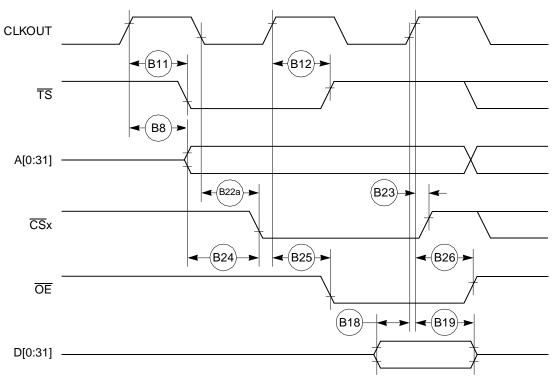


Figure 12. External Bus Read Timing (GPCM Controlled—ACS = 00)







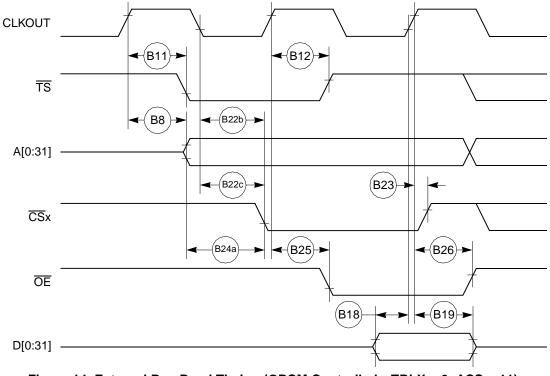


Figure 14. External Bus Read Timing (GPCM Controlled—TRLX = 0, ACS = 11)



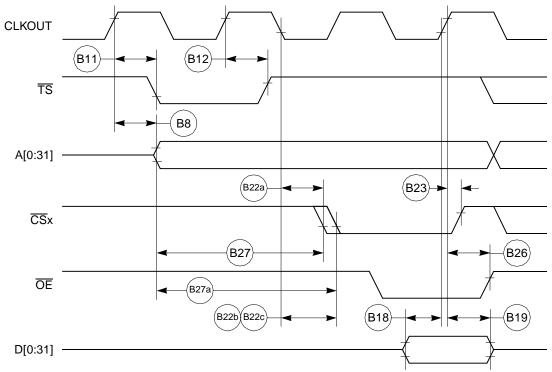
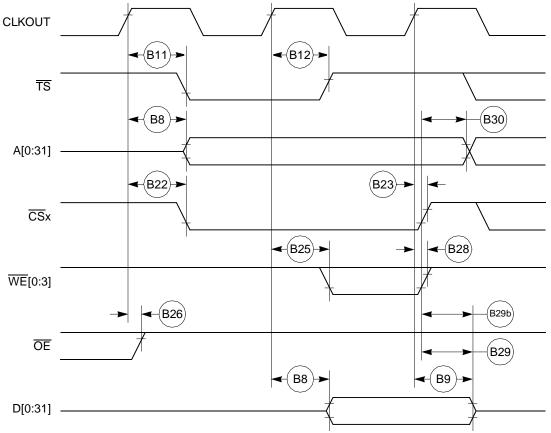


Figure 15. External Bus Read Timing (GPCM Controlled—TRLX = 1, ACS = 10, ACS = 11)



Figure 16 through Figure 18 provide the timing for the external bus write controlled by various GPCM factors.



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Figure 16. External Bus Write Timing (GPCM Controlled—TRLX = 0, CSNT = 0)
```



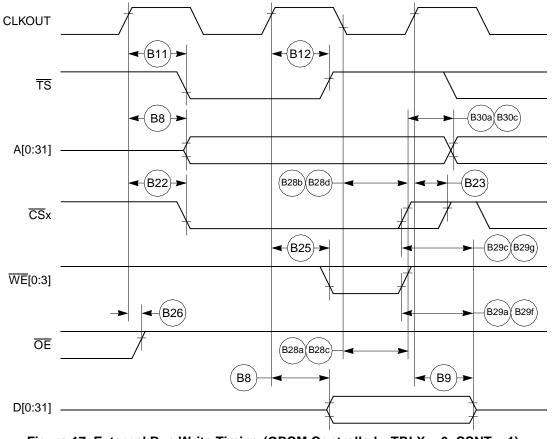
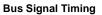


Figure 17. External Bus Write Timing (GPCM Controlled—TRLX = 0, CSNT = 1)





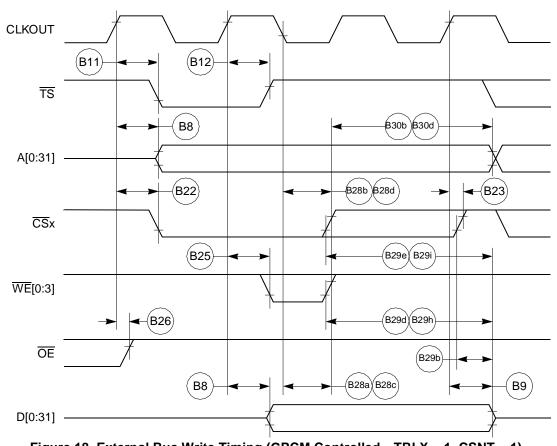
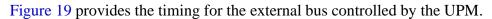


Figure 18. External Bus Write Timing (GPCM Controlled—TRLX = 1, CSNT = 1)





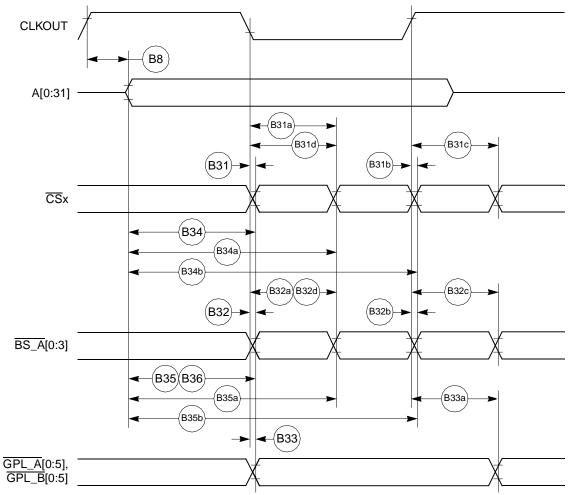


Figure 19. External Bus Timing (UPM Controlled Signals)



Figure 20 provides the timing for the asynchronous asserted UPWAIT signal controlled by the UPM.

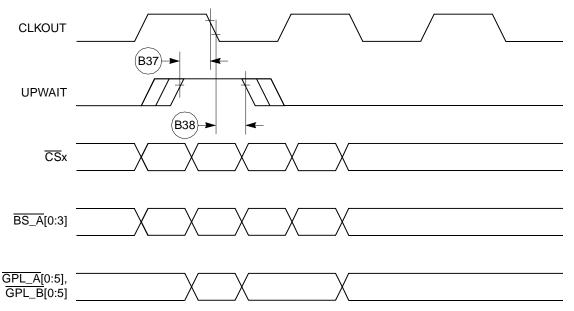


Figure 20. Asynchronous UPWAIT Asserted Detection in UPM Handled Cycles Timing

Figure 21 provides the timing for the asynchronous negated UPWAIT signal controlled by the UPM.

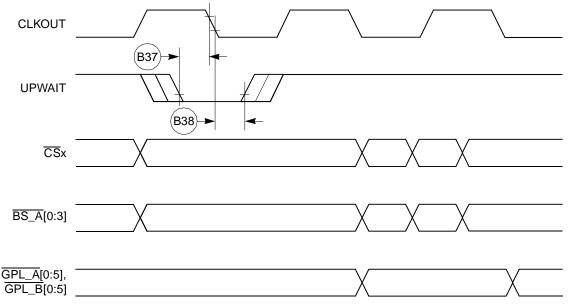


Figure 21. Asynchronous UPWAIT Negated Detection in UPM Handled Cycles Timing



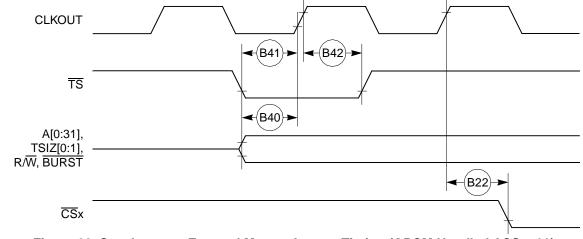


Figure 22 provides the timing for the synchronous external master access controlled by the GPCM.

Figure 22. Synchronous External Master Access Timing (GPCM Handled ACS = 00)

Figure 23 provides the timing for the asynchronous external master memory access controlled by the GPCM.

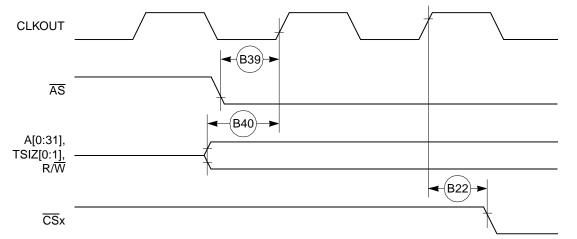




Figure 24 provides the timing for the asynchronous external master control signals negation.

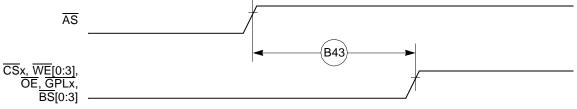


Figure 24. Asynchronous External Master—Control Signals Negation Timing



1

Table 11 provides the interrupt timing for the MPC875/MPC870.

Table 11. Interrupt Timing	
----------------------------	--

Num	Characteristic ¹	All Freq	Unit	
	Characteristic	Min	Мах	Unit
139	IRQx valid to CLKOUT rising edge (setup time)	6.00		ns
140	IRQx hold time after CLKOUT	2.00		ns
141	IRQx pulse width low	3.00		ns
142	IRQx pulse width high	3.00		ns
143	IRQx edge-to-edge time	4 × T _{CLOCKOUT}		—

The I39 and I40 timings describe the testing conditions under which the IRQ lines are tested when being defined as level sensitive. The IRQ lines are synchronized internally and do not have to be asserted or negated with reference to the CLKOUT. The I41, I42, and I43 timings are specified to allow correct functioning of the IRQ lines detection circuitry and have no direct relation with the total system interrupt latency that the MPC875/MPC870 is able to support.

Figure 25 provides the interrupt detection timing for the external level-sensitive lines.

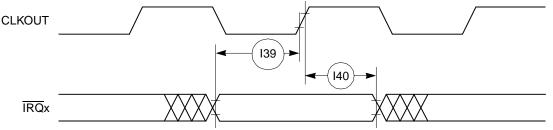


Figure 25. Interrupt Detection Timing for External Level Sensitive Lines

Figure 26 provides the interrupt detection timing for the external edge-sensitive lines.

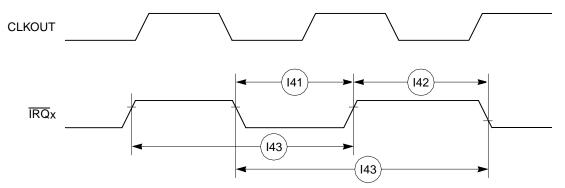


Figure 26. Interrupt Detection Timing for External Edge-Sensitive Lines



Bus Signal Timing

Table 12 shows the PCMCIA timing for the MPC875/MPC870.

Table 12. PCMCIA Timing

Num	Characteristic	33 MHz 40 MHz		MHz	z 66 MHz			80 MHz		
NUIII	Characteristic	Min	Max	Min	Max	Min	Max	Min	Max	Unit
P44	A(0:31), $\overline{\text{REG}}$ valid to PCMCIA strobe asserted ¹ (MIN = 0.75 × B1 - 2.00)	20.70		16.70		9.40	_	7.40		ns
P45	A(0:31), $\overline{\text{REG}}$ valid to ALE negation ¹ (MIN = 1.00 × B1 - 2.00)	28.30	_	23.00		13.20	_	10.50		ns
P46	CLKOUT to $\overline{\text{REG}}$ valid (MAX = 0.25 × B1 + 8.00)	7.60	15.60	6.30	14.30	3.80	11.80	3.13	11.13	ns
P47	CLKOUT to $\overline{\text{REG}}$ invalid (MIN = 0.25 × B1 + 1.00)	8.60		7.30	_	4.80	_	4.125	_	ns
P48	CLKOUT to $\overline{CE1}$, $\overline{CE2}$ asserted (MAX = 0.25 × B1 + 8.00)	7.60	15.60	6.30	14.30	3.80	11.80	3.13	11.13	ns
P49	CLKOUT to $\overline{CE1}$, $\overline{CE2}$ negated (MAX = 0.25 × B1 + 8.00)	7.60	15.60	6.30	14.30	3.80	11.80	3.13	11.13	ns
P50	CLKOUT to \overrightarrow{PCOE} , \overrightarrow{IORD} , \overrightarrow{PCWE} , \overrightarrow{IOWR} assert time (MAX = $0.00 \times B1 + 11.00$)	—	11.00	—	11.00		11.00	_	11.00	ns
P51	CLKOUT to \overrightarrow{PCOE} , \overrightarrow{IORD} , \overrightarrow{PCWE} , \overrightarrow{IOWR} negate time (MAX = 0.00 × B1 + 11.00)	2.00	11.00	2.00	11.00	2.00	11.00	2.00	11.00	ns
P52	CLKOUT to ALE assert time $(MAX = 0.25 \times B1 + 6.30)$	7.60	13.80	6.30	12.50	3.80	10.00	3.13	9.40	ns
P53	CLKOUT to ALE negate time (MAX = 0.25 × B1 + 8.00)	_	15.60	—	14.30		11.80	_	11.13	ns
P54	$\frac{\overline{PCWE}, \overline{IOWR} \text{ negated to } D(0:31)}{invalid^1 (MIN = 0.25 \times B1 - 2.00)}$	5.60	_	4.30	—	1.80	—	1.125	_	ns
P55	$\overline{\text{WAITA}}$ and $\overline{\text{WAITB}}$ valid to CLKOUT rising edge ¹ (MIN = 0.00 × B1 + 8.00)	8.00		8.00	_	8.00	—	8.00	_	ns
P56	CLKOUT rising edge to \overline{WAITA} and \overline{WAITB} invalid ¹ (MIN = 0.00 × B1 + 2.00)	2.00	_	2.00	_	2.00	—	2.00	_	ns

¹ PSST = 1. Otherwise add PSST times cycle time.

PSHT = 0. Otherwise add PSHT times cycle time.

These synchronous timings define when the WAITA signals are detected in order to freeze (or relieve) the PCMCIA current cycle. The WAITA assertion will be effective only if it is detected 2 cycles before the PSL timer expiration. See Chapter 16, "PCMCIA Interface," in the MPC885 PowerQUICC[™] Family Reference Manual.



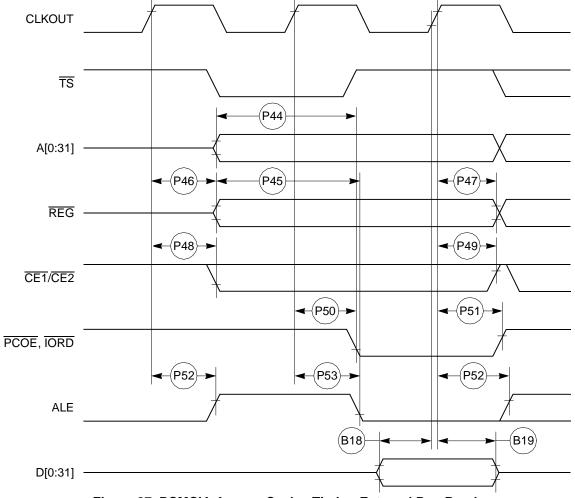


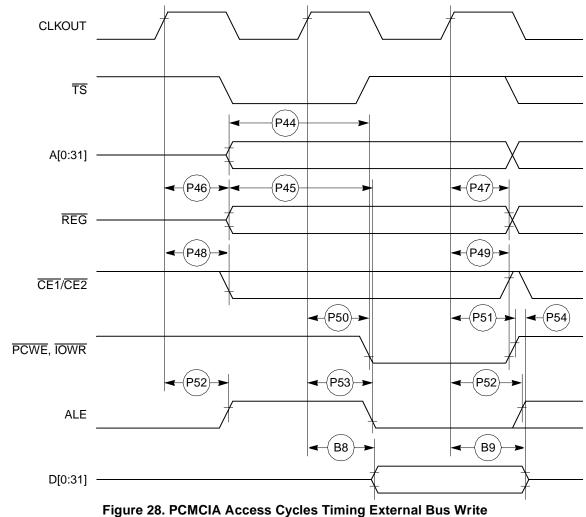
Figure 27 provides the PCMCIA access cycle timing for the external bus read.

Figure 27. PCMCIA Access Cycles Timing External Bus Read



Bus Signal Timing

Figure 28 provides the PCMCIA access cycle timing for the external bus write.



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Figure 29 provides the PCMCIA \overline{WAIT} signals detection timing.

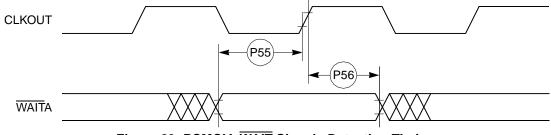


Figure 29. PCMCIA WAIT Signals Detection Timing



Table 13 shows the PCMCIA port timing for the MPC875/MPC870.

33 MHz 40 MHz 66 MHz 80 MHz Num Characteristic Unit Min Max Min Max Min Max Min Max CLKOUT to OPx valid 19.00 19.00 19.00 19.00 ____ ____ ____ ns P57 $(MAX = 0.00 \times B1 + 19.00)$ HRESET negated to OPx drive¹ 25.70 21.70 14.40 12.40 ns ____ ____ ____ ____ P58 $(MIN = 0.75 \times B1 + 3.00)$ IP_Xx valid to CLKOUT rising edge 5.00 5.00 5.00 5.00 ____ ____ ns P59 $(MIN = 0.00 \times B1 + 5.00)$ CLKOUT rising edge to IP_Xx invalid 1.00 1.00 1.00 1.00 ns ____ P60 $(MIN = 0.00 \times B1 + 1.00)$

Table 13. PCMCIA Port Timing

OP2 and OP3 only.

Figure 30 provides the PCMCIA output port timing for the MPC875/MPC870.

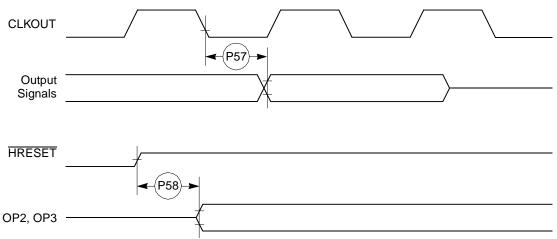


Figure 30. PCMCIA Output Port Timing

Figure 31 provides the PCMCIA input port timing for the MPC875/MPC870.

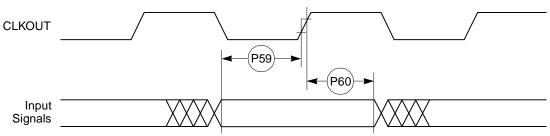


Figure 31. PCMCIA Input Port Timing



Bus Signal Timing

Table 14 shows the debug port timing for the MPC875/MPC870.

Table 14. Debug Port Timing

Num	Characteristic	All Frequ	Unit	
Num	Cildiacteristic	Min	Мах	Unit
D61	DSCK cycle time	3 × T _{CLOCKOUT}		—
D62	DSCK clock pulse width	$1.25 imes T_{CLOCKOUT}$		—
D63	DSCK rise and fall times	0.00	3.00	ns
D64	DSDI input data setup time	8.00		ns
D65	DSDI data hold time	5.00		ns
D66	DSCK low to DSDO data valid	0.00	15.00	ns
D67	DSCK low to DSDO invalid	0.00	2.00	ns

Figure 32 provides the input timing for the debug port clock.

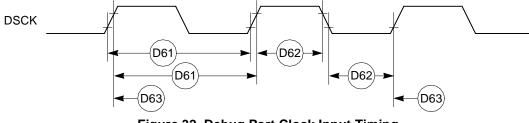


Figure 32. Debug Port Clock Input Timing

Figure 33 provides the timing for the debug port.

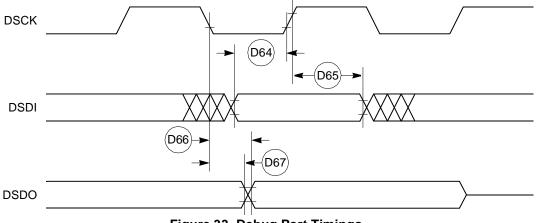


Figure 33. Debug Port Timings



Table 15 shows the reset timing for the MPC875/MPC870.

Table 15. Reset Timing

Nissia	Characteristic	33	MHz	40 1	MHz	IHz 66 MHz		80 MHz		Unit
Num	Characteristic	Min	Max	Min	Мах	Min	Max	Min	Max	Unit
R69	CLKOUT to $\overline{\text{HRESET}}$ high impedance (MAX = 0.00 × B1 + 20.00)	—	20.00	—	20.00	-	20.00	—	20.00	ns
R70	CLKOUT to $\overline{\text{SRESET}}$ high impedance (MAX = 0.00 × B1 + 20.00)	—	20.00	—	20.00	—	20.00	—	20.00	ns
R71	RSTCONF pulse width (MIN = 17.00 × B1)	515.20	—	425.00	—	257.60	—	212.50	_	ns
R72	—	_		_	_	—		_	_	—
R73	Configuration data to $\overline{\text{HRESET}}$ rising edge setup time (MIN = 15.00 × B1 + 50.00)	504.50	—	425.00	—	277.30	_	237.50	_	ns
R74	Configuration data to $\overrightarrow{\text{RSTCONF}}$ rising edge setup time (MIN = 0.00 × B1 + 350.00)	350.00	_	350.00	_	350.00	_	350.00		ns
R75	Configuration data hold time after $\overrightarrow{\text{RSTCONF}}$ negation (MIN = 0.00 × B1 + 0.00)	0.00		0.00		0.00		0.00	_	ns
R76	Configuration data hold time after HRESET negation (MIN = $0.00 \times B1 + 0.00$)	0.00	_	0.00	_	0.00		0.00		ns
R77	HRESET and RSTCONF asserted to data out drive (MAX = $0.00 \times B1 + 25.00$)	—	25.00	_	25.00	_	25.00	_	25.00	ns
R78	$\frac{RSTCONF}{RSTCONF} \text{ negated to data out high}$ impedance (MAX = 0.00 × B1 + 25.00)	—	25.00	-	25.00	-	25.00	-	25.00	ns
R79	CLKOUT of last rising edge before chip three-states $\overrightarrow{\text{HRESET}}$ to data out high impedance (MAX = 0.00 × B1 + 25.00)	—	25.00	—	25.00	—	25.00	—	25.00	ns
R80	DSDI, DSCK setup (MIN = $3.00 \times B1$)	90.90	_	75.00	_	45.50	—	37.50	_	ns
R81	DSDI, DSCK hold time (MIN = $0.00 \times B1 + 0.00$)	0.00	_	0.00	_	0.00		0.00	_	ns
R82	SRESET negated to CLKOUT rising edge for DSDI and DSCK sample (MIN = $8.00 \times B1$)	242.40	—	200.00	—	121.20	—	100.00	—	ns



Bus Signal Timing

Figure 34 shows the reset timing for the data bus configuration.

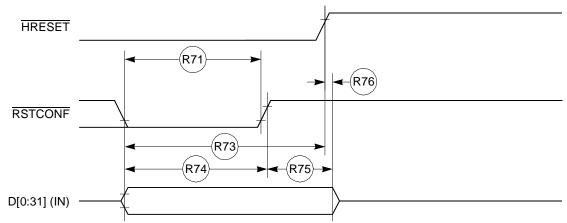
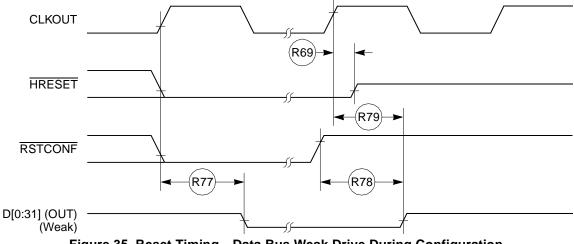




Figure 35 provides the reset timing for the data bus weak drive during configuration.



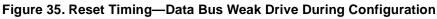
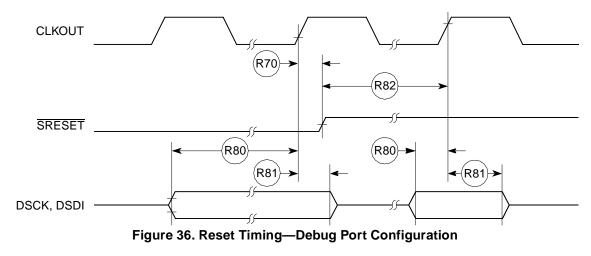


Figure 36 provides the reset timing for the debug port configuration.





12 IEEE 1149.1 Electrical Specifications

Table 16 provides the JTAG timings for the MPC875/MPC870 shown in Figure 37 through Figure 40.

Table 16. JTAG Timing

Num	Characteristic	All Freq	uencies	Unit
NUM	Characteristic	Min	Мах	Unit
J82	TCK cycle time	100.00	—	ns
J83	TCK clock pulse width measured at 1.5 V	40.00	—	ns
J84	TCK rise and fall times	0.00	10.00	ns
J85	TMS, TDI data setup time	5.00	—	ns
J86	TMS, TDI data hold time	25.00	—	ns
J87	TCK low to TDO data valid	_	27.00	ns
J88	TCK low to TDO data invalid	0.00	—	ns
J89	TCK low to TDO high impedance	_	20.00	ns
J90	TRST assert time	100.00	—	ns
J91	TRST setup time to TCK low	40.00	—	ns
J92	TCK falling edge to output valid	_	50.00	ns
J93	TCK falling edge to output valid out of high impedance	_	50.00	ns
J94	TCK falling edge to output high impedance	_	50.00	ns
J95	Boundary scan input valid to TCK rising edge	50.00	—	ns
J96	TCK rising edge to boundary scan input invalid	50.00		ns

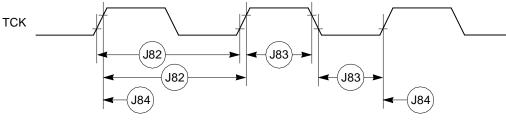


Figure 37. JTAG Test Clock Input Timing



IEEE 1149.1 Electrical Specifications

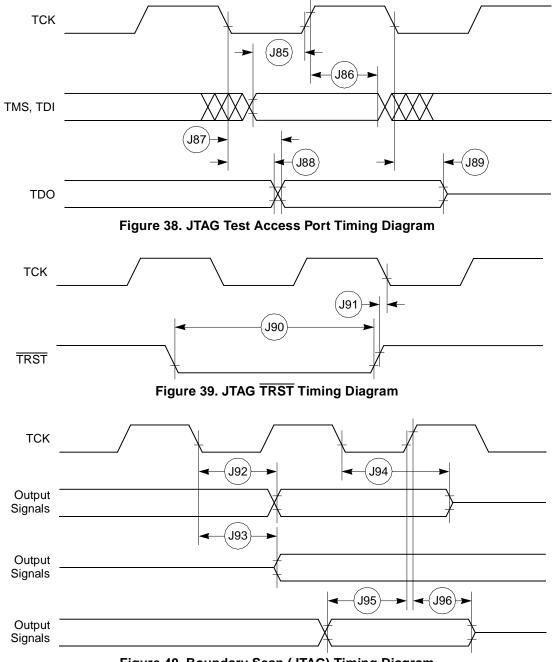


Figure 40. Boundary Scan (JTAG) Timing Diagram



13 CPM Electrical Characteristics

This section provides the AC and DC electrical specifications for the communications processor module (CPM) of the MPC875/MPC870.

13.1 Port C Interrupt AC Electrical Specifications

Table 17 provides the timings for Port C interrupts.

Table	17.	Port C	Interrupt	Timing
-------	-----	--------	-----------	--------

Num	Characteristic		33.34 MHz		
	Gharacteristic	Min	Мах	Unit	
35	Port C interrupt pulse width low (edge-triggered mode)	55	_	ns	
36	Port C interrupt minimum time between active edges	55	_	ns	

Figure 41 shows the Port C interrupt detection timing.

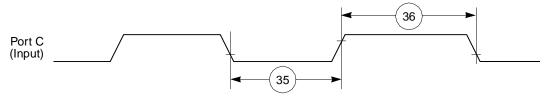


Figure 41. Port C Interrupt Detection Timing

13.2 IDMA Controller AC Electrical Specifications

Table 18 provides the IDMA controller timings as shown in Figure 42 through Figure 45.

Table 18. IDMA Controller Timing

Num	Characteristic		All Frequencies		
			Мах	Unit	
40	DREQ setup time to clock high	7	_	ns	
41	DREQ hold time from clock high ¹	TBD	_	ns	
42	SDACK assertion delay from clock high	_	12	ns	
43	SDACK negation delay from clock low	_	12	ns	
44	SDACK negation delay from TA low	_	20	ns	
45	SDACK negation delay from clock high	_	15	ns	
46	\overline{TA} assertion to rising edge of the clock setup time (applies to external \overline{TA})	7	_	ns	

¹ Applies to high-to-low mode (EDM = 1).



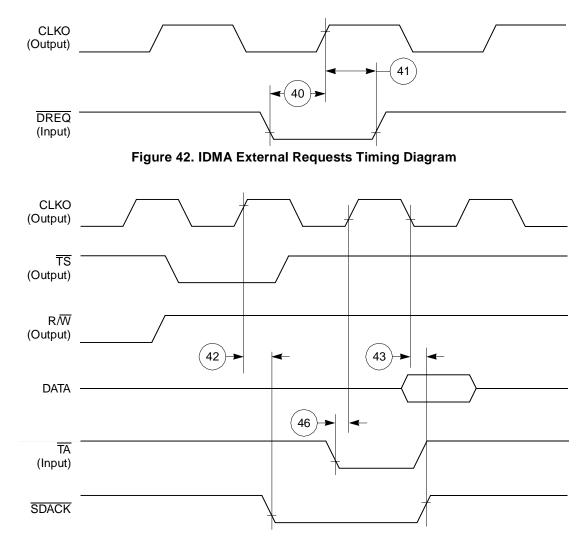


Figure 43. SDACK Timing Diagram—Peripheral Write, Externally-Generated TA



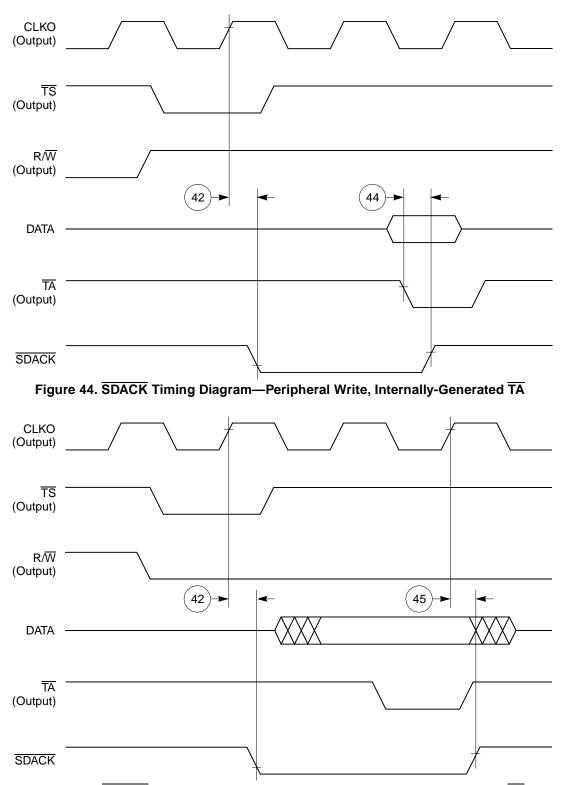


Figure 45. SDACK Timing Diagram—Peripheral Read, Internally-Generated TA



13.3 Baud Rate Generator AC Electrical Specifications

Table 19 provides the baud rate generator timings as shown in Figure 46.

Table 19. Baud Rate Generator Timing

Num	Characteristic		All Frequencies		
Num	Gharacteristic	Min	Мах	Unit	
50	BRGO rise and fall time	_	10	ns	
51	BRGO duty cycle	40	60	%	
52	BRGO cycle	40	_	ns	

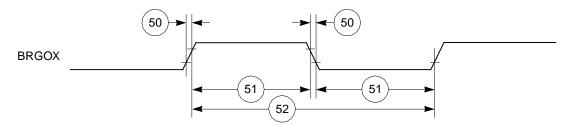


Figure 46. Baud Rate Generator Timing Diagram

13.4 Timer AC Electrical Specifications

Table 20 provides the general-purpose timer timings as shown in Figure 47.

Table	20.	Timer	Timing
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Num	Characteristic	All Freq	Unit	
Num		Min	Мах	onit
61	TIN/TGATE rise and fall time	10	_	ns
62	TIN/TGATE low time	1	_	clk
63	TIN/TGATE high time	2	_	clk
64	TIN/TGATE cycle time	3	—	clk
65	CLKO low to TOUT valid	3	25	ns



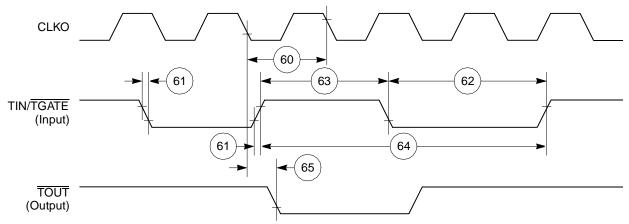


Figure 47. CPM General-Purpose Timers Timing Diagram

13.5 Serial Interface AC Electrical Specifications

Table 21 provides the serial interface (SI) timings as shown in Figure 48 through Figure 52.

Num	Characteristic	All Fre	quencies	Unit
Num	Characteristic	Min	Мах	Onit
70	L1RCLKB, L1TCLKB frequency (DSC = 0) ^{1, 2}	—	SYNCCLK/2.5	MHz
71	L1RCLKB, L1TCLKB width low $(DSC = 0)^2$	P + 10	—	ns
71a	L1RCLKB, L1TCLKB width high $(DSC = 0)^3$	P + 10	_	ns
72	L1TXDB, L1ST1 and L1ST2, L1RQ, L1CLKO rise/fall time	_	15.00	ns
73	L1RSYNCB, L1TSYNCB valid to L1CLKB edge (SYNC setup time)	20.00	—	ns
74	L1CLKB edge to L1RSYNCB, L1TSYNCB, invalid (SYNC hold time)	35.00	—	ns
75	L1RSYNCB, L1TSYNCB rise/fall time	_	15.00	ns
76	L1RXDB valid to L1CLKB edge (L1RXDB setup time)	17.00	—	ns
77	L1CLKB edge to L1RXDB invalid (L1RXDB hold time)	13.00	—	ns
78	L1CLKB edge to L1ST1 and L1ST2 valid ⁴	10.00	45.00	ns
78A	L1SYNCB valid to L1ST1 and L1ST2 valid	10.00	45.00	ns
79	L1CLKB edge to L1ST1 and L1ST2 invalid	10.00	45.00	ns
80	L1CLKB edge to L1TXDB valid	10.00	55.00	ns
80A	L1TSYNCB valid to L1TXDB valid ⁴	10.00	55.00	ns
81	L1CLKB edge to L1TXDB high impedance	0.00	42.00	ns
82	L1RCLKB, L1TCLKB frequency (DSC = 1)	_	16.00 or SYNCCLK/2	MHz
83	L1RCLKB, L1TCLKB width low (DSC = 1)	P + 10	—	ns

Table 21. SI Timing



Num	Characteristic	All Fre	Unit	
	Characteristic	Min	Мах	Unit
83a	L1RCLKB, L1TCLKB width high (DSC = 1) ³	P + 10	_	ns
84	L1CLKB edge to L1CLKOB valid (DSC = 1)	—	30.00	ns
85	L1RQB valid before falling edge of L1TSYNCB ⁴	1.00	_	L1TCLK
86	L1GRB setup time ²	42.00	_	ns
87	L1GRB hold time	42.00	_	ns
88	L1CLKB edge to L1SYNCB valid (FSD = 00) CNT = 0000, BYT = 0, DSC = 0)	_	0.00	ns

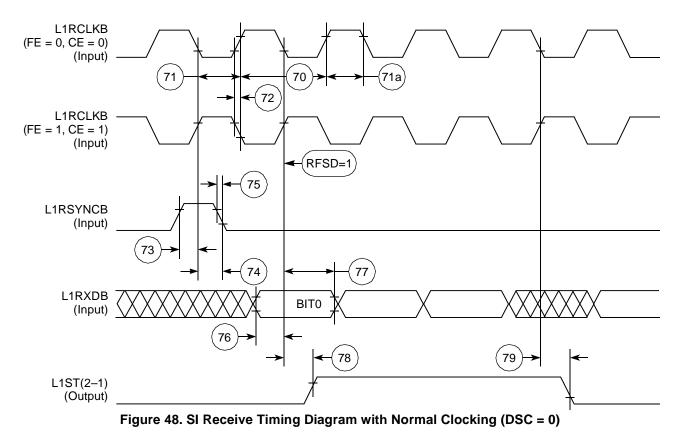
Table 21. SI Timing (continued)

¹ The ratio SYNCCLK/L1RCLKB must be greater than 2.5/1.

² These specs are valid for IDL mode only.

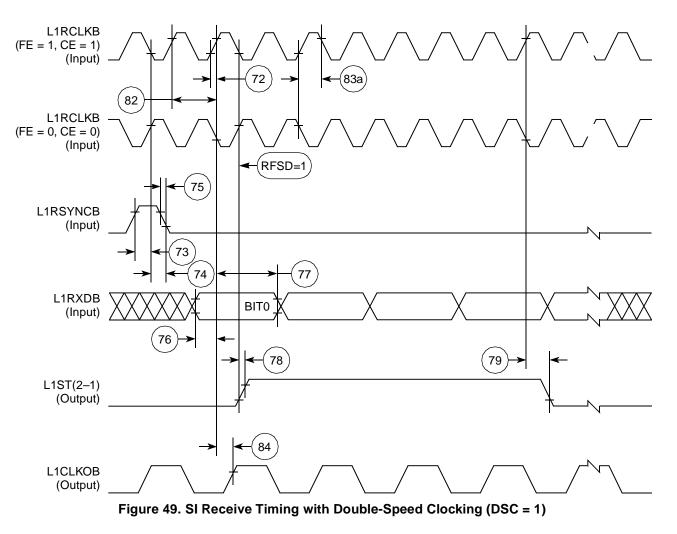
³ Where P = 1/CLKOUT. Thus, for a 25-MHz CLKO1 rate, P = 40 ns.

⁴ These strobes and TxD on the first bit of the frame become valid after the L1CLKB edge or L1SYNCB, whichever comes later.

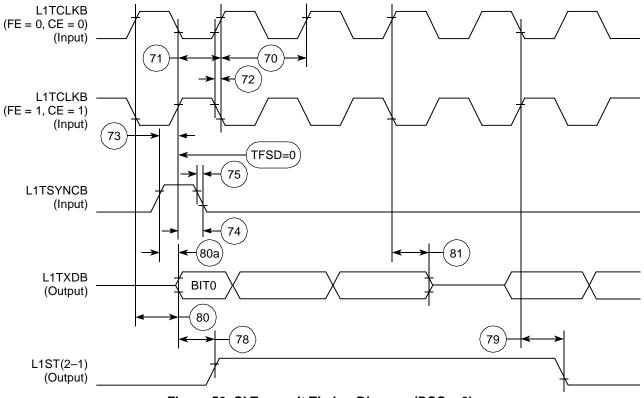




CPM Electrical Characteristics



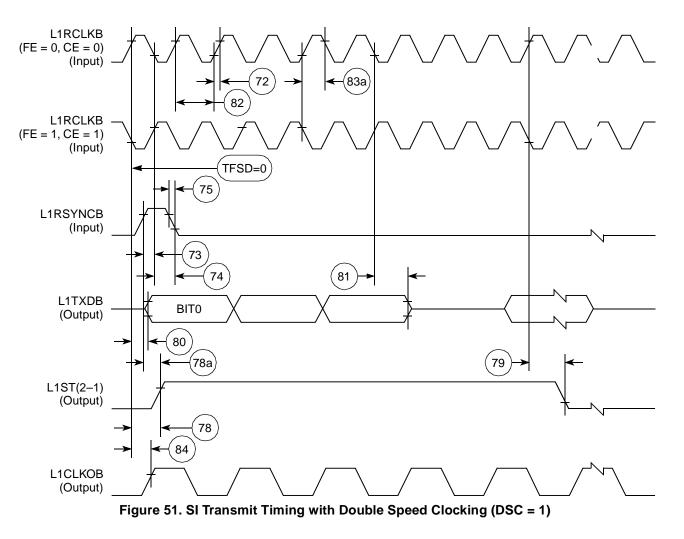




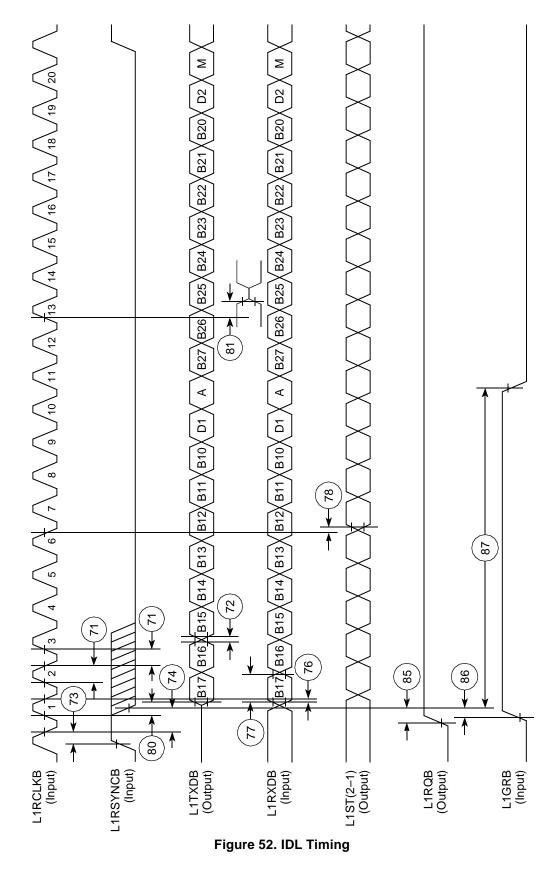




CPM Electrical Characteristics









SCC in NMSI Mode Electrical Specifications 13.6

Table 22 provides the NMSI external clock timing.

Num	Characteristic	All Frequencies		Unit	
Num	Characteristic	Min	Мах	Unit	
100	RCLK3 and TCLK3 width high ¹	1/SYNCCLK	_	ns	
101	RCLK3 and TCLK3 width low	1/SYNCCLK + 5	_	ns	
102	RCLK3 and TCLK3 rise/fall time	_	15.00	ns	
103	TXD3 active delay (from TCLK3 falling edge)	0.00	50.00	ns	
104	RTS3 active/inactive delay (from TCLK3 falling edge)	0.00	50.00	ns	
105	CTS3 setup time to TCLK3 rising edge	5.00	_	ns	
106	RXD3 setup time to RCLK3 rising edge	5.00	_	ns	
107	RXD3 hold time from RCLK3 rising edge ²	5.00	—	ns	
108	CD3 setup time to RCLK3 rising edge	5.00	—	ns	

¹ The ratios SYNCCLK/RCLK3 and SYNCCLK/TCLK3 must be greater than or equal to 2.25/1.
 ² Also applies to CD and CTS hold time when they are used as external SYNC signals.

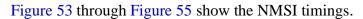
Table 23 provides the NMSI internal clock timing.

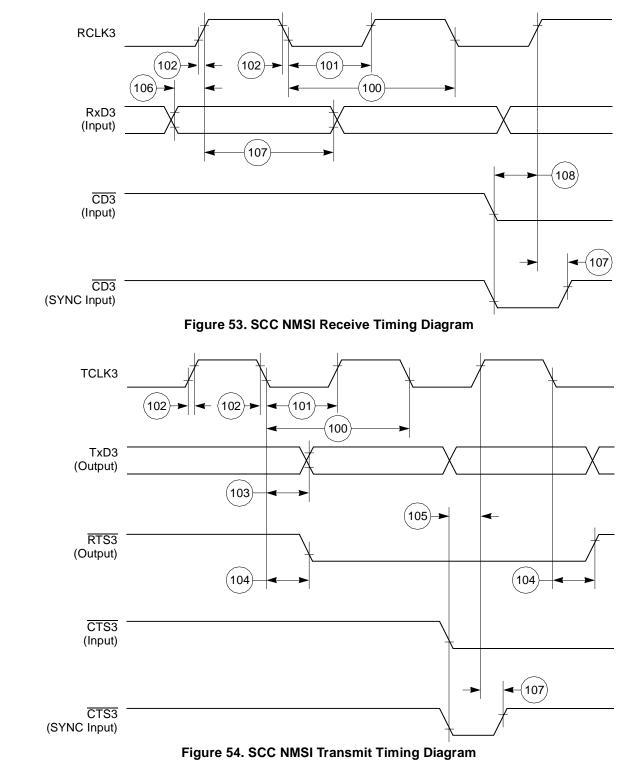
Table 23. NMSI Internal Clock Timing

Num	Characteristic	All Fre	Unit	
Num		Min	Мах	Unit
100	RCLK3 and TCLK3 frequency ¹	0.00	SYNCCLK/3	MHz
102	RCLK3 and TCLK3 rise/fall time	_	—	ns
103	TXD3 active delay (from TCLK3 falling edge)	0.00	30.00	ns
104	RTS3 active/inactive delay (from TCLK3 falling edge)	0.00	30.00	ns
105	CTS3 setup time to TCLK3 rising edge	40.00	—	ns
106	RXD3 setup time to RCLK3 rising edge	40.00	—	ns
107	RXD3 hold time from RCLK3 rising edge ²	0.00	—	ns
108	CD3 setup time to RCLK3 rising edge	40.00	—	ns

The ratios SYNCCLK/RCLK3 and SYNCCLK/TCLK3 must be greater or equal to 3/1.
 Also applies to CD and CTS hold time when they are used as external SYNC signals.











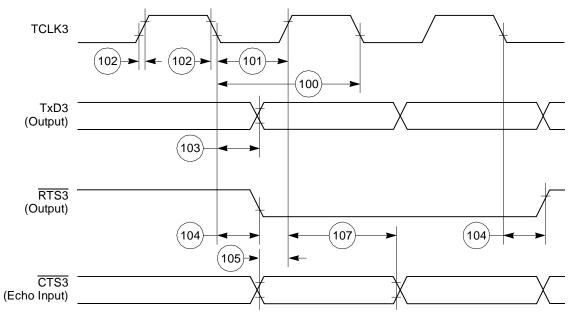


Figure 55. HDLC Bus Timing Diagram

13.7 Ethernet Electrical Specifications

Table 24 provides the Ethernet timings as shown in Figure 56 through Figure 58.

Table 24. Ethernet Timing

Num		All Frequencies		Unit
Num	Characteristic	Min	Мах	Unit
120	CLSN width high	40		ns
121	RCLK3 rise/fall time	—	15	ns
122	RCLK3 width low	40	—	ns
123	RCLK3 clock period ¹	80	120	ns
124	RXD3 setup time	20	—	ns
125	RXD3 hold time	5	—	ns
126	RENA active delay (from RCLK3 rising edge of the last data bit)	10	—	ns
127	RENA width low	100	—	ns
128	TCLK3 rise/fall time	—	15	ns
129	TCLK3 width low	40	—	ns
130	TCLK3 clock period ¹	99	101	ns
131	TXD3 active delay (from TCLK3 rising edge)	—	50	ns
132	TXD3 inactive delay (from TCLK3 rising edge)	6.5	50	ns
133	TENA active delay (from TCLK3 rising edge)	10	50	ns
134	TENA inactive delay (from TCLK3 rising edge)	10	50	ns



Num	Characteristic	All Frequencies		Unit
		Min	Мах	onit
138	CLKO1 low to SDACK asserted ²	_	20	ns
139	CLKO1 low to SDACK negated ²	_	20	ns

Table 24. Ethernet Timing (continued)

¹ The ratios SYNCCLK/RCLK3 and SYNCCLK/TCLK3 must be greater than or equal to 2/1.

² SDACK is asserted whenever the SDMA writes the incoming frame DA into memory.

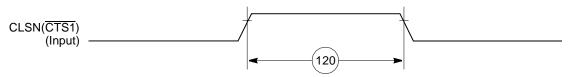


Figure 56. Ethernet Collision Timing Diagram

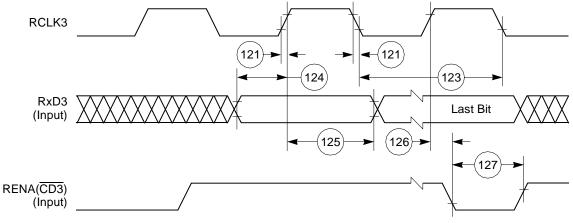
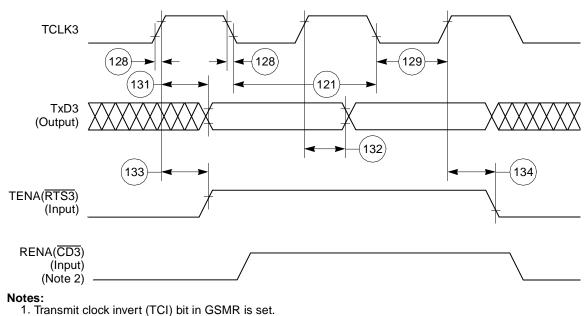


Figure 57. Ethernet Receive Timing Diagram







2. If RENA is negated before TENA or RENA is not asserted at all during transmit, then the CSL bit is set in the buffer descriptor at the end of the frame transmission.

Figure 58. Ethernet Transmit Timing Diagram

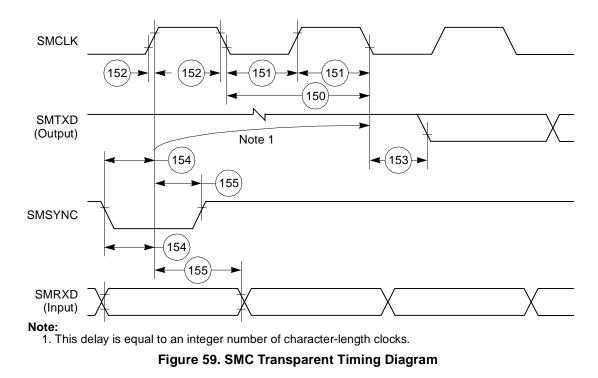
13.8 SMC Transparent AC Electrical Specifications

Table 25 provides the SMC transparent timings as shown in Figure 59.

Num	Characteristic	All Frequencies		Unit
Num		Min	Мах	Unit
150	SMCLK clock period ¹	100	_	ns
151	SMCLK width low	50		ns
151A	SMCLK width high	50	_	ns
152	SMCLK rise/fall time	—	15	ns
153	SMTXD active delay (from SMCLK falling edge)	10	50	ns
154	SMRXD/SMSYNC setup time	20	—	ns
155	RXD1/SMSYNC hold time	5	—	ns

¹ SYNCCLK must be at least twice as fast as SMCLK.





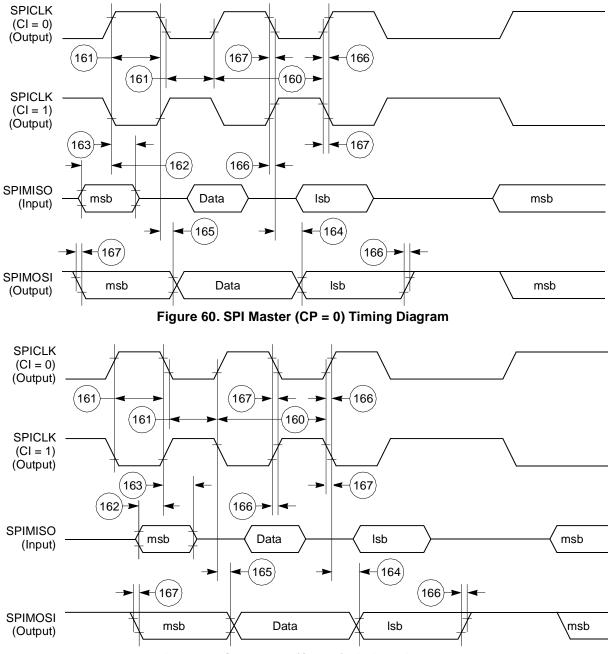
13.9 SPI Master AC Electrical Specifications

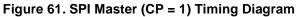
Table 26 provides the SPI master timings as shown in Figure 60 and Figure 61.

Table 26. SPI Master Timing

Num	Characteristic	All Frequencies		Umit
Num		Min	Мах	Unit
160	Master cycle time	4	1024	t _{cyc}
161	Master clock (SCK) high or low time	2	512	t _{cyc}
162	Master data setup time (inputs)	15	_	ns
163	Master data hold time (inputs)	0	_	ns
164	Master data valid (after SCK edge)	_	10	ns
165	Master data hold time (outputs)	0	_	ns
166	Rise time output	—	15	ns
167	Fall time output	_	15	ns







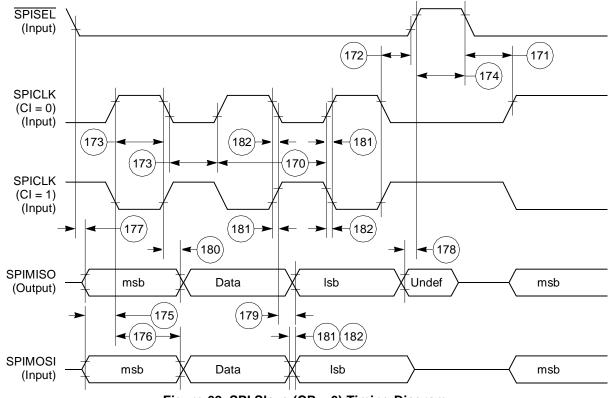


13.10 SPI Slave AC Electrical Specifications

Table 27 provides the SPI slave timings as shown in Figure 62 and Figure 63.

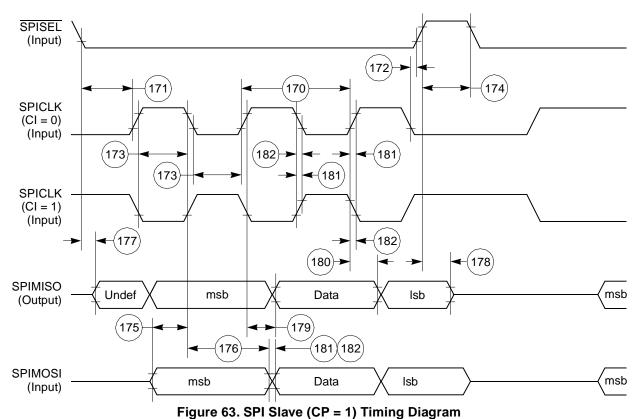
Table 27. SPI Slave Timing

Num	Characteristic	All Frequencies		Unit
Num		Min	Мах	onit
170	Slave cycle time	2	—	t _{cyc}
171	Slave enable lead time	15	—	ns
172	Slave enable lag time	15	—	ns
173	Slave clock (SPICLK) high or low time	1	—	t _{cyc}
174	Slave sequential transfer delay (does not require deselect)	1	—	t _{cyc}
175	Slave data setup time (inputs)	20	—	ns
176	Slave data hold time (inputs)	20	—	ns
177	Slave access time	_	50	ns









13.11 I²C AC Electrical Specifications

Table 28 provides the I^2C (SCL < 100 kHz) timings.

Table 28. I²C Timing (SCL < 100 kHz)</th>

Num	Characteristic	All Frequencies		Unit
Num		Min	Max	Unit
200	SCL clock frequency (slave)	0	100	kHz
200	SCL clock frequency (master) ¹	1.5	100	kHz
202	Bus free time between transmissions	4.7	_	μs
203	Low period of SCL	4.7	_	μs
204	High period of SCL	4.0	_	μs
205	Start condition setup time	4.7	-	μs
206	Start condition hold time	4.0	-	μs
207	Data hold time	0		μs
208	Data setup time	250		ns
209	SDL/SCL rise time		1	μs



Num	Characteristic		uencies	Unit
Num		Min	Max	onit
210	SDL/SCL fall time	_	300	ns
211	Stop condition setup time	4.7		μs

Table 28. I²C Timing (SCL < 100 kHz) (continued)

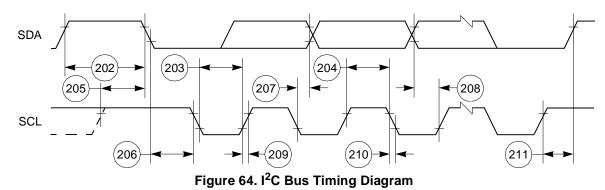
SCL frequency is given by SCL = BRGCLK_frequency/((BRG register + 3) × pre_scalar × 2). The ratio SYNCCLK/(BRGCLK/pre_scalar) must be greater than or equal to 4/1.

Table 29 provides the I^2C (SCL > 100 kHz) timings.

Num	Characteristic	All Frequencies	uencies	Unit		
Nulli	Characteristic	Expression	Min	Max	oint	
200	SCL clock frequency (slave)	fSCL	0	BRGCLK/48	Hz	
200	SCL clock frequency (master) ¹	fSCL	BRGCLK/16512	BRGCLK/48	Hz	
202	Bus free time between transmissions	_	1/(2.2 × fSCL)	_	S	
203	Low period of SCL	_	1/(2.2 × fSCL)	_	S	
204	High period of SCL	—	1/(2.2 × fSCL)	—	S	
205	Start condition setup time	—	1/(2.2 × fSCL)	—	S	
206	Start condition hold time	—	1/(2.2 × fSCL)	—	S	
207	Data hold time	—	0	—	S	
208	Data setup time	—	1/(40 × fSCL)	—	S	
209	SDL/SCL rise time	—	—	1/(10 × fSCL)	S	
210	SDL/SCL fall time	—	—	$1/(33 \times \text{fSCL})$	S	
211	Stop condition setup time	—	1/2(2.2 × fSCL)	_	S	

SCL frequency is given by SCL = BRGCLK_frequency/((BRG register + 3) × pre_scalar × 2). The ratio SYNCCLK/(BRGCLK/pre_scalar) must be greater than or equal to 4/1.

Figure 64 shows the I^2C bus timing.





14 USB Electrical Characteristics

This section provides the AC timings for the USB interface.

14.1 USB Interface AC Timing Specifications

The USB Port uses the transmit clock on SCC1. Table 30 lists the USB interface timings.

Table 30. USB Interface AC Timing Specifications

Name	Characteristic	All Freq	uencies	Unit
		Min Max	onn	
US1	USBCLK frequency of operation ¹ Low speed Full speed	6	6 8	MHz
US4	USBCLK duty cycle (measured at 1.5 V)	45	55	%

¹ USBCLK accuracy should be ±500 ppm or better. USBCLK may be stopped to conserve power.

15 FEC Electrical Characteristics

This section provides the AC electrical specifications for the Fast Ethernet controller (FEC). Note that the timing specifications for the MII signals are independent of system clock frequency (part speed designation). Also, MII signals use TTL signal levels compatible with devices operating at either 5.0 or 3.3 V.

15.1 MII and Reduced MII Receive Signal Timing

The receiver functions correctly up to a MII_RX_CLK maximum frequency of 25 MHz + 1%. The reduced MII (RMII) receiver functions correctly up to a RMII_REFCLK maximum frequency of 50 MHz + 1%. There is no minimum frequency requirement. In addition, the processor clock frequency must exceed the MII_RX_CLK frequency -1%.

Table 31 provides information on the MII receive signal timing.

Num	Characteristic	Min	Мах	Unit
M1	MII_RXD[3:0], MII_RX_DV, MII_RX_ER to MII_RX_CLK setup	5	_	ns
M2	MII_RX_CLK to MII_RXD[3:0], MII_RX_DV, MII_RX_ER hold	5	_	ns
M3	MII_RX_CLK pulse width high	35%	65%	MII_RX_CLK period
M4	MII_RX_CLK pulse width low	35%	65%	MII_RX_CLK period
M1_RMII	RMII_RXD[1:0], RMII_CRS_DV, RMII_RX_ERR to RMII_REFCLK setup	4	_	ns
M2_RMII	RMII_REFCLK to RMII_RXD[1:0], RMII_CRS_DV, RMII_RX_ERR hold	2		ns

Table 31. MII Receive Signal Timing



Figure 65 shows MII receive signal timing.

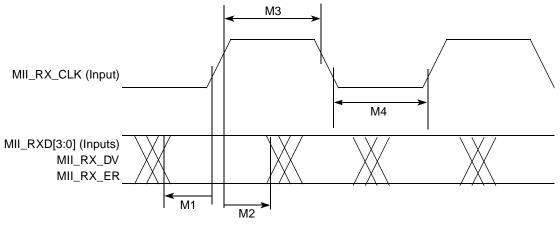


Figure 65. MII Receive Signal Timing Diagram

15.2 MII and Reduced MII Transmit Signal Timing

The transmitter functions correctly up to a MII_TX_CLK maximum frequency of 25 MHz + 1%. There is no minimum frequency requirement. In addition, the processor clock frequency must exceed the MII_TX_CLK frequency -1%.

Table 32 provides information on the MII transmit signal timing.

Table 32. M	III Transmit	Signal Timing
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Num	Characteristic	Min	Max	Unit
M5	MII_TX_CLK to MII_TXD[3:0], MII_TX_EN, MII_TX_ER invalid	5	_	ns
M6	MII_TX_CLK to MII_TXD[3:0], MII_TX_EN, MII_TX_ER valid		25	ns
M7	MII_TX_CLK pulse width high	35%	65%	MII_TX_CLK period
M8	MII_TX_CLK pulse width low	35%	65%	MII_TX_CLK period
M20_RMII	RMII_TXD[1:0], RMII_TX_EN to RMII_REFCLK setup	4	_	ns
M21_RMII	RMII_TXD[1:0], RMII_TX_EN data hold from RMII_REFCLK rising edge	2	_	ns



Figure 66 shows the MII transmit signal timing diagram.

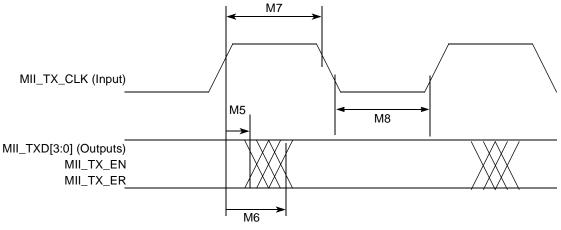


Figure 66. MII Transmit Signal Timing Diagram

15.3 MII Async Inputs Signal Timing (MII_CRS, MII_COL)

Table 33 provides information on the MII async inputs signal timing.

Table 33. MII Async Inputs Signal Timing

Nu	Characteristic	Min	Max	Unit
M	MII_CRS, MII_COL minimum pulse width	1.5	—	MII_TX_CLK period

Figure 67 shows the MII asynchronous inputs signal timing diagram.

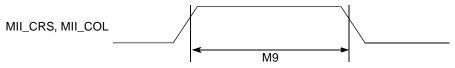


Figure 67. MII Async Inputs Timing Diagram

15.4 MII Serial Management Channel Timing (MII_MDIO, MII_MDC)

Table 34 provides information on the MII serial management channel signal timing. The FEC functions correctly with a maximum MDC frequency in excess of 2.5 MHz.

Table 34. MII Serial Management Channel Tir	ning
---	------

Num	Characteristic	Min	Мах	Unit
M10	MII_MDC falling edge to MII_MDIO output invalid (minimum propagation delay)	0	_	ns
M11	MII_MDC falling edge to MII_MDIO output valid (max prop delay)		25	ns
M12	MII_MDIO (input) to MII_MDC rising edge setup	10	—	ns
M13	MII_MDIO (input) to MII_MDC rising edge hold	0	—	ns
M14	MII_MDC pulse width high	40%	60%	MII_MDC period
M15	MII_MDC pulse width low	40%	60%	MII_MDC period



Figure 68 shows the MII serial management channel timing diagram.

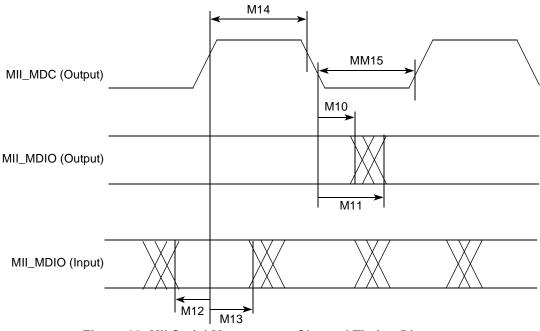


Figure 68. MII Serial Management Channel Timing Diagram



16 Mechanical Data and Ordering Information

Table 35 identifies the packages and operating frequencies available for the MPC875/MPC870.

Package Type	Temperature (T _J)	Frequency (MHz)	Order Number
Plastic ball grid array ZT suffix—Leaded VR suffix—Lead-Free are available as needed	0°C to 95°C	66	KMPC875ZT66 KMPC870ZT66 MPC875ZT66 MPC870ZT66
		80	KMPC875ZT80 KMPC870ZT80 MPC875ZT80 MPC870ZT80
		133	KMPC875ZT133 KMPC870ZT133 MPC875ZT133 MPC870ZT133
Plastic ball grid array CZT suffix—Leaded CVR suffix—Lead-Free are available as needed	-40°C to 100°C	66	KMPC875CZT66 KMPC870CZT66 MPC875CZT66 MPC870CZT66
		133	KMPC875CZT133 KMPC870CZT133 MPC875CZT133 MPC870CZT133

Table 35. Available MPC875/MPC870 Packages/Frequencies



16.1 Pin Assignments

Figure 69 shows the JEDEC pinout of the PBGA package as viewed from the top surface. For additional information, see the *MPC885 PowerQUICC Family User's Manual*.

NOTE

The pin numbering starts with B2 in order to conform to the JEDEC standard for 23-mm body size using a 16×16 array.

2 7 8 9 10 11 12 13 14 3 4 5 6 15 16 17 O O O O EXTCLK MODCK1 \bigcup_{ALEA} \bigcirc CS3 O N/C в Ο O OP0 $O_{\overline{CS5}}$ MODCK2 $\bigcirc_{\overline{BB}}$ $\bigcup_{\overline{TS}}$ \bigcup_{TA} O_{CS2} С \bigcirc \cap О \bigcirc \bigcirc \bigcirc \bigcirc \bigcirc \bigcirc \bigcirc \bigcirc \bigcirc CE1A RSTCONF SRESET BADDR29 OP1 ALEB IRQ2 BDIP GPLAB3 GPLA0 IPA7 D \bigcirc \bigcirc Ο IPA2 WAITA PORESET XTAL EXTAL BADDR30 IPB1 BG GPLA4 GPLA5 $\overline{\mathsf{WR}}$ CE2A CS7 WE2 WE1 IPA4 Е Ο \bigcirc \bigcirc \bigcirc \bigcirc \bigcirc \bigcirc Ο \bigcirc \bigcirc О Ο Ο Ο Ο Ο HRESET BADDR28 IRQ4 CS1 GPLB4 CS4 GPLAB2 BSA1 BSA2 **IRQ3 WEO** D31 IPA5 IPA3 VSSSYN VDDSYN F Ο \bigcirc \bigcirc \bigcirc O_{CS6} Ο Ο O \bigcirc O Ο \bigcirc \bigcirc \odot Ο Ο BSAO BSA3 D30 IPA6 IPA1 VSSSYN VDDL VDDL OE TSIZ0 A31 D29 G \bigcirc Ο Ο \bigcirc Ο \bigcirc O VDDH \bigcirc \bigcirc O VDDH \bigcirc Ο \bigcirc \bigcirc Ο Ο D28 CLKOUT IPA0 WE3 TSI71 A22 D7 D26 A26 A18 н Ο Ο Ο Ο \bigcirc \bigcirc \bigcirc \bigcirc \bigcirc \bigcirc Ο \bigcirc Ο \bigcirc Ο Ο D22 D6 D24 D25 VDDL VDDH GND VDDH VDDL A28 A30 A25 A24 O D20 O D21 () A20 O A29 J Ο \bigcirc \bigcirc Ο Ο \bigcirc \bigcirc O A23 O A21 Ο Ο \bigcirc D19 D18 GND Κ Ο Ο Ο \bigcirc \bigcirc \bigcirc \bigcirc \bigcirc Ο Ο Ο 0 Ο Ο \bigcirc \bigcirc D15 D16 D14 VDDL GND VDDL D5 A14 A19 A27 A17 O D2 () A12 L \bigcirc Ο 0 \bigcirc \bigcirc \bigcirc \bigcirc \bigcirc \bigcirc \bigcirc \bigcirc Ο D27 DO A15 A10 A16 D3 O VDDH () A8 Μ \bigcirc Ο Ο Ο 0 \bigcirc \bigcirc \bigcirc \bigcirc 0 \bigcirc \bigcirc Ο A11 **IRQ0** MII_MDIO A2 A13 D11 D9 D12 PE18 0 0 \bigcirc 0 \bigcirc \bigcirc Ο \bigcirc \bigcirc 0 Ν \bigcirc 0 Ο \bigcirc Ο \bigcirc D13 IRQ7 PA2 VDDL VDDL PB26 PB27 A1 A6 A7 D10 D1 A9 \bigcirc \bigcirc \bigcirc Ο \bigcirc \bigcirc \bigcirc \bigcirc Ο \bigcirc Р Ο \bigcirc Ο \bigcirc \bigcirc PE14 PE31 D23 D17 PE22 PA0 PA4 PC6 PA6 PC11 TDO PA15 A3 Α5 R О O Ο Ο \bigcirc \bigcirc \bigcirc \bigcirc \bigcirc \bigcirc \bigcirc \bigcirc O PB28 O PC15 \bigcirc_{A0} \bigcirc PE19 PE28 PE30 PA11 MII_COL PA7 PA10 тск PB29 PE25 PA3 D4 D8 \bigcirc \bigcirc Ο \bigcirc Ο \bigcirc \bigcirc \bigcirc Ο \bigcirc \bigcirc \bigcirc \bigcirc т \bigcirc Ο \bigcirc PD8 PB31 PE27 PE17 PE21 PC7 PB19 PC12 N/C PB30 PE26 PA1 PE15 PB24 TDI TMS U O PE20 O PE23 MII-TX-EN PE16 O PE29 O PE24 O PC13 O MII-CRS O PC10 O PB23 O PB25 O PA14 O N/C

NOTE: This is the top view of the device.

Figure 69. Pinout of the PBGA Package—JEDEC Standard



Table 36 contains a list of the MPC875/MPC870 input and output signals and shows multiplexing and pin assignments.

Name	Pin Number	Туре
A[0:31]	R16, N14, M14, P15, P17, P16, N15, N16, M15, N17, L14, M16, L15, M17, K14, L16, L17, K17, G17, K15, J16, J15, G16, J14, H17, H16, G15, K16, H14, J17, H15, F17	Bidirectional Three-state (3.3 V only)
TSIZO, REG	F16	Bidirectional Three-state (3.3 V only)
TSIZ1	G14	Bidirectional Three-state (3.3 V only)
RD/WR	D13	Bidirectional Three-state (3.3 V only)
BURST	B9	Bidirectional Three-state (3.3 V only)
BDIP, GPL_B5	C13	Output
TS	C11	Bidirectional Active pull-up (3.3 V only)
TA	C12	Bidirectional Active pull-up (3.3 V only)
TEA	B12	Open-drain
BI	B13	Bidirectional Active pull-up (3.3 V only)
IRQ2, RSV	C9	Bidirectional Three-state (3.3 V only)
IRQ4, KR, RETRY, SPKROUT	E9	Bidirectional Three-state (3.3 V only)
D[0:31]	L5, N3, L3, L2, R2, K2, H3, G2, R3, M3, N2, M2, M4, N4, K5, K3, K4, P3, J2, J3, J4, J5, H2, P2, H4, H5, G5, L4, G3, F2, F3, E2	Bidirectional Three-state (3.3 V only)
CR, IRQ3	E10	Input
FRZ, IRQ6	B10	Bidirectional Three-state (3.3 V only)
BR	B11	Bidirectional (3.3 V only)
BG	D10	Bidirectional (3.3 V only)
BB	C10	Bidirectional Active pull-up (3.3 V only)
ĪRQ0	M6	Input (3.3 V only)
ĪRQ1	P5	Input (3.3 V only)
ĪRQ7	N5	Input (3.3 V only)
<u>CS</u> [0:5]	B14, E11, C14, B15, E13, B16	Output

Table 36. Pin Assignments—JEDEC Standard



Name	Pin Number	Туре
CS6, CE1_B	F12	Output
CS7, CE2_B	D15	Output
WE0, BS_B0, IORD	E15	Output
WE1, BS_B1, IOWR	D17	Output
WE2, BS_B2, PCOE	D16	Output
WE3, BS_B3, PCWE	G13	Output
BS_A[0:3]	F14, E16, E17, F15	Output
GPL_A0, GPL_B0	C17	Output
OE, GPL_A1, GPL_B1	F13	Output
<u>GPL_A</u> [2:3], <u>GPL_B</u> [2:3], <u>CS</u> [2–3]	E14, C16	Output
UPWAITA, GPL_A4	D11	Bidirectional (3.3 V only)
UPWAITB, GPL_B4	E12	Bidirectional
GPL_A5	D12	Output
PORESET	D5	Input (3.3 V only)
RSTCONF	C3	Input (3.3 V only)
HRESET	E7	Open-drain
SRESET	C4	Open-drain
XTAL	D6	Analog output
EXTAL	D7	Analog input (3.3 V only)
CLKOUT	G4	Output
EXTCLK	B4	Input (3.3 V only)
TEXP	B3	Output
ALE_A	B7	Output
CE1_A	C15	Output
CE2_A	D14	Output
WAIT_A	D4	Input (3.3 V only)
IP_A0	G6	Input (3.3 V only)
IP_A1	F5	Input (3.3 V only)
IP_A2, IOIS16_A	D3	Input (3.3 V only)
IP_A3	E4	Input (3.3 V only)
IP_A4	D2	Input (3.3 V only)
IP_A5	E3	Input (3.3 V only)



Name	Pin Number	Туре
IP_A6	F4	Input (3.3 V only)
IP_A7	C2	Input (3.3 V only)
ALE_B, DSCK	C8	Bidirectional Three-state (3.3 V only)
IP_B[0:1], IWP[0:1], VFLS[0:1]	B8, D9	Bidirectional (3.3 V only)
OP0	B6	Bidirectional (3.3 V only)
OP1	C6	Output
OP2, MODCK1, STS	B5	Bidirectional (3.3 V only)
OP3, MODCK2, DSDO	B2	Bidirectional (3.3 V only)
BADDR[28:29]	E8, C5	Output
BADDR30, REG	D8	Output
ĀS	C7	Input (3.3 V only)
PA15, USBRXD	P14	Bidirectional
PA14, USBOE	U16	Bidirectional (Optional: open-drain)
PA11, RXD4, MII1-TXD0, RMII1-TXD0	R9	Bidirectional (Optional: open-drain) (5-V tolerant)
PA10, MII1-TXERR, TIN4, CLK7	R12	Bidirectional (Optional: open-drain) (5-V tolerant)
PA7, CLK1, BRGO1, TIN1	R11	Bidirectional
PA6, CLK2, TOUT1	P11	Bidirectional
PA4, CTS4, MII1-TXD1, RMII-TXD1	P7	Bidirectional
PA3, MII1-RXER, RMII1-RXER, BRGO3	R5	Bidirectional (5-V tolerant)
PA2, MII1-RXDV, RMII1-CRS_DV, TXD4	N6	Bidirectional (5-V tolerant)
PA1, MII1-RXD0, RMII1-RXD0, BRGO4	Τ4	Bidirectional (5-V tolerant)
PA0, MII1-RXD1, RMII1-RXD1, TOUT4	P6	Bidirectional (5-V tolerant)
PB31, <u>SPISEL</u> , MII1-TXCLK, RMII1-REFCLK	Т5	Bidirectional (Optional: open-drain) (5-V tolerant)



Name	Pin Number	Туре
PB30, SPICLK	T17	Bidirectional (Optional: open-drain) (5-V tolerant)
PB29, SPIMOSI	R17	Bidirectional (Optional: open-drain) (5-V tolerant)
PB28, SPIMISO, BRGO4	R14	Bidirectional (Optional: open-drain) (5-V tolerant)
PB27, I2CSDA, BRGO1	N13	Bidirectional (Optional: open-drain)
PB26, I2CSCL, BRGO2	N12	Bidirectional (Optional: open-drain)
PB25, SMTXD1	U13	Bidirectional (Optional: open-drain) (5-V tolerant)
PB24, SMRXD1	T12	Bidirectional (Optional: open-drain) (5-V tolerant)
PB23, SDACK1, SMSYN1	U12	Bidirectional (Optional: open-drain)
PB19, MII1-RXD3, RTS4	T11	Bidirectional (Optional: open-drain)
PC15, DREQ0, L1ST1	R15	Bidirectional (5-V tolerant)
PC13, MII1-TXD3, SDACK1	U9	Bidirectional (5-V tolerant)
PC12, MII1-TXD2, TOUT1	T15	Bidirectional (5-V tolerant)
PC11, USBRXP	P12	Bidirectional
PC10, USBRXN, TGATE1	U11	Bidirectional
PC7, <u>CTS4</u> , L1TSYNCB, USBTXP	T10	Bidirectional (5-V tolerant)
PC6, CD4 , L1RSYNCB, USBTXN	P10	Bidirectional (5-V tolerant)
PD8, RXD4, MII-MDC, RMII-MDC	ТЗ	Bidirectional (5-V tolerant)
PE31, CLK8, L1TCLKB, MII1-RXCLK	P9	Bidirectional (Optional: open-drain)
PE30, L1RXDB, MII1-RXD2	R8	Bidirectional (Optional: open-drain)



Name	Pin Number	Туре
PE29, MII2-CRS	U7	Bidirectional (Optional: open-drain)
PE28, TOUT3, MII2-COL	R7	Bidirectional (Optional: open-drain)
PE27, L1RQB, MII2-RXERR, RMII2-RXERR	Т6	Bidirectional (Optional: open-drain)
PE26, L1CLKOB, MII2-RXDV, RMII2-CRS_DV	T2	Bidirectional (Optional: open-drain)
PE25, RXD4, MII2-RXD3, L1ST2	R4	Bidirectional (Optional: open-drain)
PE24, SMRXD1, BRGO1, MII2-RXD2	U8	Bidirectional (Optional: open-drain)
PE23, TXD4, MII2-RXCLK, L1ST1	U4	Bidirectional (Optional: open-drain)
PE22, TOUT2, MII2-RXD1, RMII2-RXD1, SDACK1	P4	Bidirectional (Optional: open-drain)
PE21, TOUT1, MII2-RXD0, RMII2-RXD0	Т9	Bidirectional (Optional: open-drain)
PE20, MII2-TXER	U3	Bidirectional (Optional: open-drain)
PE19, L1TXDB, MII2-TXEN, RMII2-TXEN	R6	Bidirectional (Optional: open-drain)
PE18, SMTXD1, MII2-TXD3	M5	Bidirectional (Optional: open-drain)
PE17, TIN3, CLK5, BRGO3, SMSYN1, MII2-TXD2	Т8	Bidirectional (Optional: open-drain)
PE16, L1RCLKB, CLK6, MII2-TXCLK, RMII2-REFCLK	U6	Bidirectional (Optional: open-drain)
PE15, TGATE1, MII2-TXD1, RMII2-TXD1	Т7	Bidirectional
PE14, MII2-TXD0, RMII2-TXD0	P8	Bidirectional
TMS	T14	Input (5-V tolerant)
TDI, DSDI	T13	Input (5-V tolerant)
TCK, DSCK	R13	Input (5-V tolerant)
TRST	U14	Input (5-V tolerant)

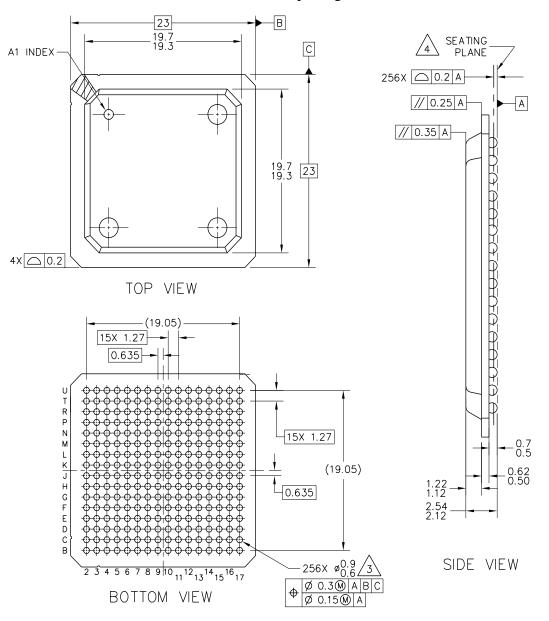


Name	Pin Number	Туре
TDO, DSDO	P13	Output (5-V tolerant)
MII1_CRS	U10	Input
MII_MDIO	M13	Bidirectional (5-V tolerant)
MII1_TX_EN, RMII1_TX_EN	U5	Output (5-V tolerant)
MII1_COL	R10	Input
V _{SSSYN}	E5	PLL analog GND
V _{SSSYN1}	F6	PLL analog GND
V _{DDSYN}	E6	PLL analog V _{DD}
GND	H8, H9, H10, H11, J8, J9, J10, J11, K8, K9, K10, K11, L8, L9, L10, L11, U15	Power
V _{DDL}	F7, F8, F9, F10, F11, H6, H13, J6, J13, K6, K13, L6, L13, N7, N8, N9, N10, N11	Power
V _{DDH}	G7, G8, G9, G10, G11, G12, H7, H12, J7, J12, K7, K12, L7, L12, M7, M8, M9, M10, M11, M12	Power
N/C	B17, T16, U2, U17	No connect



16.2 Mechanical Dimensions of the PBGA Package

Figure 70 shows the mechanical dimensions of the PBGA package.



NOTES:

- 1. ALL DIMENSIONS ARE IN MILLIMETERS.
- 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.
- 3. MAXIMUM SOLDER BALL DIAMETER MEASURED PARALLEL TO DATUM A.
- 4. DATUM A, THE SEATING PLANE, IS DEFINED BY THE SPHERICAL CROWNS OF THE SOLDER BALLS.
- **Note:** Solder sphere composition is 95.5%Sn 45%Ag 0.5%Cu for MPC875/MPC870VRXXX. Solder sphere composition is 62%Sn 36%Pb 2%Ag for MPC875/MPC870ZTXXX.

Figure 70. Mechanical Dimensions and Bottom Surface Nomenclature of the PBGA Package

MPC875/MPC870 PowerQUICC™ Hardware Specifications, Rev. 4



Document Revision History

17 Document Revision History

Table 37 lists significant changes between revisions of this hardware specification.

Table 37. Document Revision History

Revision Number	Date	Changes
0	2/2003	Initial release.
0.1	3/2003	Took out the time-slot assigner and changed the SCC for SCC3 to SCC4.
0.2	5/2003	Changed the package drawing, removed all references to Data Parity. Changed the SPI Master Timing Specs. 162 and 164. Added the RMII and USB timing. Added the 80-MHz timing.
0.3	5/2003	Made sure the pin types were correct. Changed the Features list to agree with the MPC885.
0.4	5/2003	Corrected the signals that had overlines on them. Made corrections on two pins that were typos.
0.5	5/2003	Changed the pin descriptions for PD8 and PD9.
0.6	5/2003	Changed a few typos. Put back the I ² C. Put in the new reset configuration, corrected the USB timing.
0.7	6/2003	Changed the pin descriptions per the June 22 spec, removed Utopia from the pin descriptions, changed PADIR, PBDIR, PCDIR and PDDIR to be 0 in the Mandatory Reset Config.
0.8	8/2003	Added the reference to USB 2.0 to the Features list and removed 1.1 from USB on the block diagrams.
0.9	8/2003	Changed the USB description to full-/low-speed compatible.
1.0	9/2003	Added the DSP information in the Features list. Put a new sentence under Mechanical Dimensions. Fixed table formatting. Nontechnical edits. Released to the external web.
1.1	10/2003	Added TDMb to the MPC875 Features list, the MPC875 Block Diagram, added 13.5 Serial Interface AC Electrical Specifications, and removed TDMa from the pin descriptions.
2.0	12/2003	Changed DBGC in the Mandatory Reset Configuration to X1. Changed the maximum operating frequency to 133 MHz. Put the timing in the 80 MHz column. Put in the orderable part numbers. Rounded the timings to hundredths in the 80 MHz column. Put the pin numbers in footnotes by the maximum currents in Table 6. Changed 22 and 41 in the Timing. Put TBD in the Thermal table.

MPC875/MPC870 PowerQUICC[™] Hardware Specifications, Rev. 4



Revision Number	Date	Changes
3.0	1/07/2004 7/19/2004	 Added sentence to Spec B1A about EXTCLK and CLKOUT being in alignment for integer values. Added a footnote to Spec 41 specifying that EDM = 1. Added the thermal numbers to Table 4. Added RMII1_EN under M1II_EN in Table 36, Pin Assignments. Added a table footnote to Table 6, DC Electrical Specifications, about meeting the V_{IL} Max of the I²C Standard. Put the new part numbers in the Ordering Information Section.
4	08/2007	 Updated template. On page 1, updated first paragraph and added a second paragraph. After Table 2, inserted a new figure showing the undershoot/overshoot voltage (Figure 3) and renumbered the rest of the figures. In Table 10, for reset timings B29f and B29g added footnote indicating that the formula only applies to bus operation up to 50 MHz. In Figure 5, changed all reference voltage measurement points from 0.2 and 0.8 V to 50% level. In Table 18, changed num 46 description to read, "TA assertion to rising edge"



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